

Power management Guide 2019



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More than 25 years of technology innovation in power management directly resulting in value creation for our customers, from products to system solutions

There is no secret when designing a power management system or sub-system: regardless of the final use, whether it is an energy generation or distribution system, a power supply or a LED driving circuit, an industrial SMPS or an electric vehicle power application, it must provide high efficiency and low standby power, as well as high power density, reliability and safety, while respecting specific cost constraints.

The key enablers for any such system with the above features are discrete and integrated power semiconductors, which play a crucial role in every step along the energy supply chain and, when applied in conjunction with advanced control technologies, can drive continuous improvement in energy savings for homeowners and communities, and ultimately for the entire planet.

The technological innovation that has been at the core of ST's strategy for more than 25 years is the reason why ST today can offer an extensive range of cutting-edge products for power and energy management. ST's portfolio includes higher-efficiency power technologies such as silicon carbide power discretes, HV and LV power MOSFETs, IGBTs and customized power modules, diodes and protection devices, AC-DC converters and controllers, DC-DC converters, linear voltage regulators and analog ICs, battery management ICs, digital controllers and STM32 microcontrollers, MOSFET and IGBT gate drivers. Moreover, ST offers a variety of high performance sensors as well as wireless and wired connectivity ICs to complement the latest smart power electronics applications with additional sensor-driven features and monitoring functions.

ST is also committed to the development of GaN HEMT (High Electron Mobility Transistor) devices, which represent a major step forward in power electronics by providing high-frequency operation with increased efficiency and higher power density than silicon based transistors.

Additionally, we provide a comprehensive range of reference designs and hardware and software evaluation and development tools, including the eDesignSuite tool that can help engineers design and optimize their high efficiency power solutions.



ENERGY GENERATION AND DISTRIBUTION

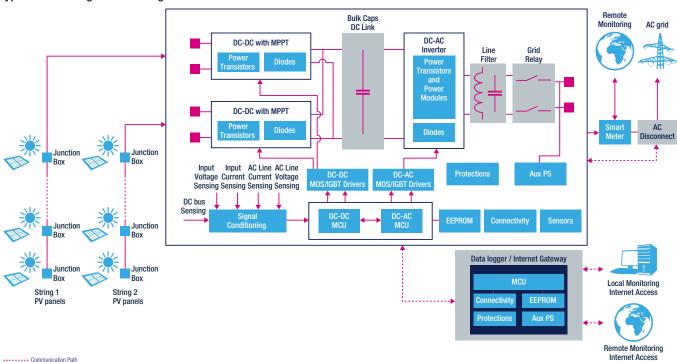
Solar Centralized Generation - Solar Inverters (String and Central)

String and central inverter are the most common power conversion systems used for grid-connected solar applications. They comprise a DC-DC conversion stage, to adapt voltage levels and implement the Maximum Power Point tracking (MPPT) function to maximize energy transfer from the panel, and a DC-AC conversion stage to correctly shape current and voltage waveforms transferred to the AC grid. The inverter has an anti-islanding function that guarantees safety in case of AC disconnection. With power ranging from a few kilowatts for string and multi-string inverters to tens or hundreds of kilowatts for central inverter solutions, the trend is to use topologies with very high input voltages (up to 1500 V).

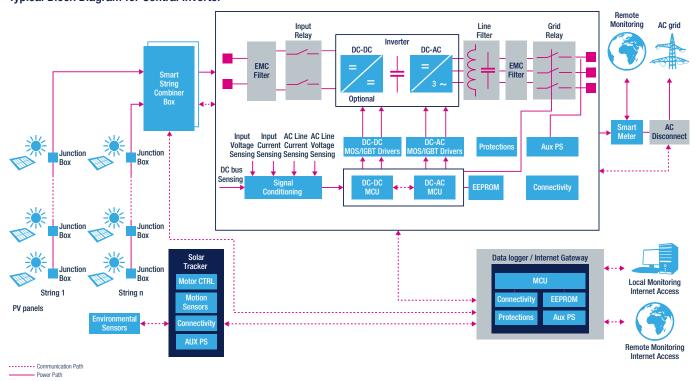
We offer a broad range of silicon-carbide (SiC) power MOSFETs - with the industry's highest operating junction temperature of 200 °C - and trench-gate field-stop IGBTs, that can be also combined into our high-efficiency ACEPACK power modules. Together with galvanically-isolated gate drivers and high-performance STM32 microcontrollers we enable engineers to design high-efficiency string and central inverters. In addition we have a range of wireless and wired connectivity solutions.



Typical Block Diagram for String Inverter



Typical Block Diagram for Central Inverter



ST'S PRODUCT OFFERING FOR STRING AND CENTRAL SOLAR INVERTER

	Power MOSFFETs	IGBTs	Power Modules	Diodes
	600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2	600 V V series STG*V60DF		
	600 V MDmesh DM6 ST*60DM6	650 V HB series STG*H65DFB		600 V Ultrafast STTH*06
Inverter Power Stage	650 V MDmesh M5 ST*65M5	650 V HB2 series STG*H65DFB2	ACEPACK	STTH*R06 1200 V Ultrafast
inverter rower stage	1200 V MDmesh K5	650 V M series STG*M65DF2	Power Modules	STTH*12 SiC Diodes
	ST*N120K5 SiC MOSFETs	1200 V H series STG*H120DF2		STPSC*065 STPSC*12
	SCT*N65G2, SCT*N120, SCT*N120G2	1200 V M series STG*M120DF3		
	MCUs	MOSFET and IGBT Gate Drivers	Protections	Connectivity
Inverter Driving & Control stage	STM32F334 STM32F1 STM32F3 STM32F4 STM32F7	HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* Multiple LS Gate Drivers	TVS for power rail surge protection SMA6F, SMB15F series	Bluetooth Low Energy Power Line Transceivers Ethernet Transceivers
	STM32F7 STM32H7 STM32G4	PM8834 Single LS Gate Drivers PM88*1	·	USB
	MCUs	EEPROM	Protections	Connectivity
Data Logger/Internet Gateway	STM32F0 STM32G0 STM32F1 STM32F3	Standard Serial EEPROM	ESD and High Speed Port (HSP) series for Ethernet and USB protection	Bluetooth Low Energy Power Line Transceivers Ethernet Transceivers USB
	Motor CTRL	Motion Sensors	Enviromental Sensors	Connectivity
Solar Tracker	3-phase Field Oriented Control	Accelerometer IIS3DHHC, LIS2DW12, IIS2DH	Pressure - LPS22HB Temperature - STLM20	Bluetooth Low Energy
	(FOC)	Magnetometer-IIS2MDC eCompass-ISM303DAC	Temperature - STTS751	USB
		6 axis IMU-ISM330DLC	Humidity - HTS221	

Note: * is used as a wildcard character for related part number

Solar Distributed Generation - Microinverter

In residential photovoltaic systems Microinverters are often used as an alternative to string inverters to perform the DC to AC power conversion at panel level helping maximize energy yield and mitigate problems related to partial shading, dirt or single panel failures. In a micro inverter there is a DC-DC converter - implementing Maximum Power Point Tracking (MPPT) - and a DC-AC inverter to shape current and voltage for injection into the AC grid. Data — including voltage, current and power generated - from all the micro inverters in the installation are collected by a concentrator and dispatched to a local or remote monitoring and control access point.

Our solution includes MDmesh and STripFET power MOSFETs, high-voltage, galvanically isolated gate drivers, high-voltage silicon-carbide (SiC) diodes together with high-performance STM32

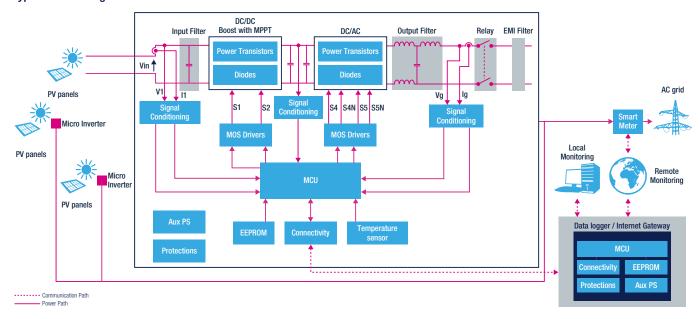
microcontrollers - providing a set of dedicated peripherals to help implement complex power conversion control algorithms. A range of wireless and wired connectivity solutions including multi-standard power line modems complete the solution.

ST'S PRODUCT OFFERING FOR MICROINVERTER

	Power MOSFFETs	Diodes	Protections	Signal Conditioning
Microinverter Power Stage	80 V-100 V STripFET F7 ST*N8F7, ST*N10F7 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 800 V-900 V MDmesh K5 ST*80K5, ST*90K5 SiC MOSFET SCT*N65G2	600 V Ultrafast STTH*R06 1200 V Ultrafast STTH*S12 SiC Diodes STPSC*065 STPSC*12	TVS for power rail surge protection SMA6F, SMB15F series	Precision Op Amps (<50 MHz) TS*, TSV*, LMV* Current Sensing TSC*
	MCUs	MOSFET and IGBT Gate Drivers	Sensors	Connectivity
Microinverter Driving & Control stage	STM32F334 STM32F1 STM32F3 STM32F4 STM32F7 STM32H7 STM32G4	HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1	Temperature - STLM20 Temperature - STTS751 Temperature - LM135 Protections ESD and High Speed Port (HSP) series for Ethernet and USB protection	Bluetooth Low Energy Power Line Transceivers Ethernet Transceivers USB EEPROM Standard Serial EEPROM
	MCUs	EEPROM	Protections	Connectivity
Data Logger/Internet Gateway	STM32F0 STM32G0	Standard Serial EEPROM	ESD and High Speed Port (HSP) series for Dataline ESD and EOS protection	RS232, RS485 Power Line Transceivers Ethernet Transceivers USB

Note: * is used as a wildcard character for related part number

Typical Block Diagram



Solar Distributed Generation - Power Optimizer

In architectures based on the use of power optimizers, the maximum power point tracking (MPPT) function is performed at the level of each photovoltaic panel so they all operate at their maximum power point. This results in an improved energy yield of the overall solar system compared to traditional string or central inverter based architectures.

Power optimizers can help minimize a system's design constraints as well as improve reliability and safety — by helping ensure compliance with the latest NEC 2017 regulations that require rapid shut-down in the event of grid disconnection, while at the same time reducing maintenance costs.



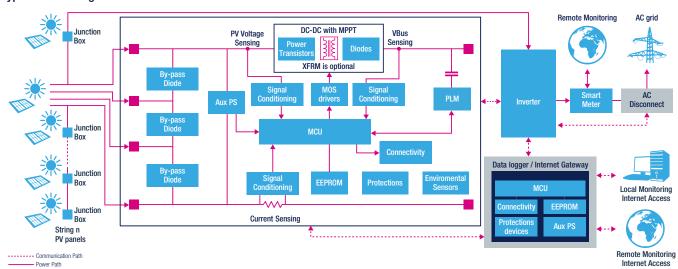
We provide high-performance STM32 microcontrollers as well as high-efficiency STripFET F7 MOSFTEs, Diodes, SiC MOSFETs and trench-gate field-stop IGBTs, field-stop IGBTs, galvanically-isolated gate drivers and power line communication solutions to help achieve superior efficiency and reliability for the implementation of power optimizer based architectures.

ST'S PRODUCT OFFERING FOR POWER OPTIMIZER

	MCUs	Power MOSFETs	Gate Drivers	By Pass Diodes	Diodes	Protections	Connectivity
Power Optimizer	STM32F334 STM32F0 STM32G0 STM32F3 STM32G4	60 V to 100 V STripFET F7 ST*N6F7 ST*N8F7 ST*N10F7	HV HB Gate Drivers L649*	Drivers 45 V FERD 100 V FERD	protection	Bluetooth Low Energy Power Line Transceivers Signal Conditioning Precision Op Amps (<50 MHz) TS*, TSV*, LMV* Current Sensing TSC*	
	MCUs	Power MOSFETs	Isolated Gate	IGBTs	Diodes	Protections	Connectivity
Inverter	STM32F334 STM32F1 STM32F3 STM32F4 STM32F7 STM32H7 STM32G4	SiC MOSFETS SCT*N120 SCT*N120G2	Drivers STGAP* Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1	600 V V series STG*V60DF 650 V HB series STG*H65DFB 650 V HB2 series STG*H65DFB2 650 V M series STG*M65DF2 1200 V H series STG*H120DF2 1200 V M series STG*M120DF3	600 V Ultrafast STTH*06 STTH*R06 SiC Diodes STPSC*065 STPSC*12	TVS for power rail surge protection SMA6F, SMB15F series ESD and High Speed Port (HSP) series for Ethernet and USB protection	Bluetooth Low Energy Power Line Transceivers Ethernet Transceivers USB
	MCUs	EEPROM				Protections	Connectivity
Data Logger/ Internet Gateway	STM32F0 STM32G0	Standard Serial EEPROM				ESD and High Speed Port (HSP) series for Dataline ESD and EOS protection	Bluetooth Low Energy Power Line Transceivers USB

Note: * is used as a wildcard character for related part number

Typical Block Diagram



Energy Distribution - Home & Commercial Battery Storage Systems

The adoption of energy storage devices, whose reserve capacity can be used for balancing purposes, peak-load shaving or to shift loads, is increasingly widespread in energy distribution networks.

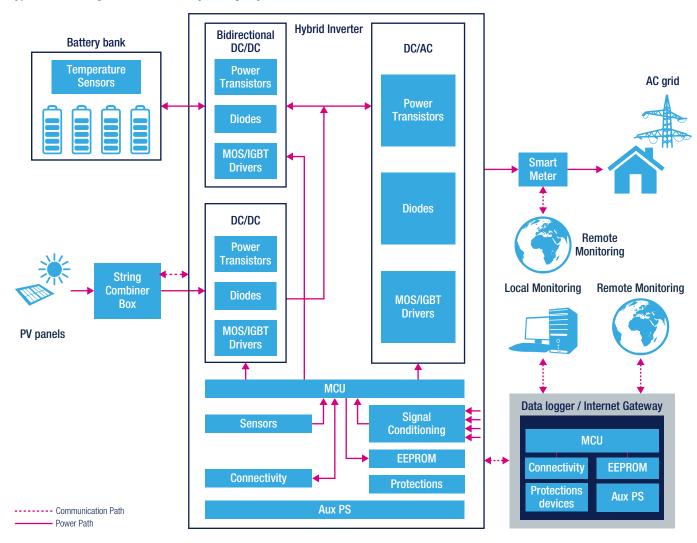
Two use cases are particularly important: the use in residential or commercial building to help reduce consumers' electricity bills by reducing energy consumption from the grid during peak hours and to help avoid stability and voltage drop issues associated with the fast-charging schedules of the increasing number of electric vehicles (EV).

Interacting with the grid, the batteries and potentially with solar panels, the power converters at the heart of these systems must operate with high-efficiency and superior reliability over time.

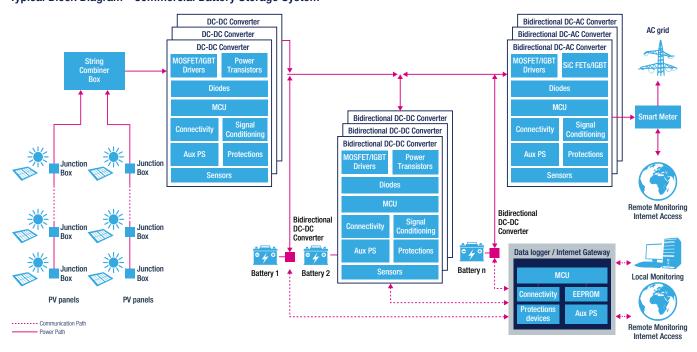
We can provide a range of power discretes including silicon-carbide (SiC) and silicon power transistors, ACEPACK power modules, silicon-carbide (SiC) and silicon diodes, isolated gate drivers and high-performance STM32 microcontrollers as well as energy metering ICs to help develop high-efficiency commercial battery storage systems.



Typical Block Diagram - Home Battery Storage System



Typical Block Diagram - Commercial Battery Storage System



ST'S PRODUCT OFFERING FOR HOME & COMMERCIAL BATTERY STORAGE SYSTEMS

	Power MOSFETs	IGBTs & Power Modules	Diodes	MOSFET and IGBT Gate Drivers	Protections
DC-DC Converter & Bidirectional DC-DC Converter Power Stage DC-AC Converter Power Stage	40 V-100 V STripFET F7¹ ST*N4F7, ST*N6F7, ST*N8F7, ST*N10F7 600 V-650 V MDmesh M2 ST*60M2, ST*65M2 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 600 V MDmesh DM6 ST*60DM6 800 V to 1200 V MDmesh K5 ST*80K5, ST*9*K5 ST*105K5, ST*120K5 SiC MOSFETS SCT*N65G2 SCT*N120 SCT*N120G2	600 V V series STG*V60DF 650 V HB series STG*H65DFB 650 V HB2 series STG*H65DFB2 650 V M series STG*M65DF2 1200 V H series STG*H120DF2 1200 V M series STG*M120DF3	600 V Ultrafast STTH*06 STTH*R06 800 V to 1200 V Ultrafast STTH*08 STTH*10 STTH*12 SiC Diodes STPSC*065 STPSC*12	HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1	TVS for power rail surge protection SMA6F, SMB15F series ESD and High Speed Port (HSP) series for Ethernet and USB protection
System Control Stage	MCUS STM32F334 STM32F1 STM32F3 STM32F4 STM32G4	Signal Conditioning Precision Op Amps (<50 MHz) TS*, TSV*, LMV* Current Sensing TSC*	EEPROM Standard Serial EEPROM	Sensors Temperature STLM20 STTS751 LM135Z	Connectivity RS485-RS232 Interfaces Power Line Transceivers Ethernet Transceivers USB
	MCUs	Protections	EEPROM	Connect	
Data Logger/ Internet Gateway	STM32F0 STM32G0 STM32F1 STM32F3	ESD and High Speed Port (HSP) series for Dataline ESD and EOS protection	Standard Serial EEPROM	RS485-RS232 Power Line Tra Bluetooth Lo Ethernet Trar USB RF SuBGHz Transceivers² (ir	ansceivers w Energy nsceivers

POWER SUPPLIES

Auxiliary SMPS

Many appliances and equipment require the availability of an auxiliary power source (SMPS) that works separately from the main power supply to support, for instance, stand-by operation. Power ratings can vary from a few to a few tens of watts for these auxiliary supplies, which can be either isolated or non-isolated. To ensure good performance, engineers must choose the power topology — including fixed frequency or quasi-resonant flyback — that best meets the efficiency, size, safety and cost requirements.

ST offers a wide portfolio of highly-integrated high voltage converters for applications up to 20 W, with an extremely low total stand-by consumption – down to less than 4 mW – and breakdown voltages as high as 1050 V. In addition to PWM switching controllers, power MOSFETs and diodes, we offer an extensive set of evaluation and development tools as well as reference designs to help engineers develop high-efficiency and compact auxiliary power supply solutions.

Isolated Auxiliary SMPS

In the power range up to 20 W, ST helps the designers of high-power-density and cost-effective isolated auxiliary power supplies with higher switching frequencies solutions to minimize transformer and output capacitor size.

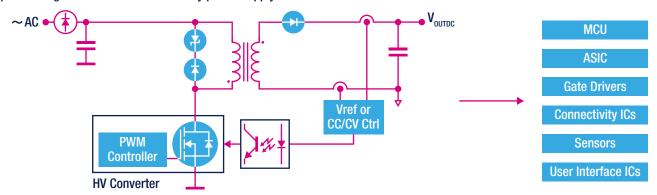
In the 20 to 75 W power range, the need to meet increasingly tight efficiency and stand-by requirements for auxiliary power supplies has pushed the use of quasi-resonant topologies replacing more mainstream fixed frequency based designs.

ST'S RECOMMENDED PRODUCTS FOR ISOLATED AUXILIARY SMPS

		HV cor	overters	Offline controllers	HV Power MOSFETs	MOSFET Protection	Clamping diodes	Voltage Ref CC/CV Ctrl	Output diodes	LDO
	PSR-CV									
lated pack	Regulation with optocoupler	VIPer*5 VIPer*7 VIPer*8	VIPer0P VIPer*1 VIPer*6 VIPer122 ALTAIR*	STCH02 STCH03 L6566B L6566BH L6565	800 V to 1700 V MDmesh K5 ST*80K5, ST*9*K5, ST*105K5, ST*120K5, ST*150K5, ST*12N170K5 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 SiC MOSFET SCT*N65G2	SMA6F, SMB15F series	600 V Ultrafast STTH*06 800 V to 1200 V Ultrafast STTH*08 STTH*10 STTH*12	Voltage Reference T*431 T*432 Voltage and Current Ctrl TSM*, SEA*	Schottky, FERD STPS* FERD*45 FERD*50 FERD*60 FER*100	Low Dropout (LD0) Linear Regulators LDF LDFM LDK220 LDK320 LDL212

Note: * is used as a wildcard character for related part number

Typical configuration for isolated auxiliary power supply



MAIN EVALUATION BOARDS AND REFERENCE DESIGNS



STEVAL-VP26K01F

Three outputs, isolated flyback converter with extended input voltage range for Smart Meter and Power Line Communication



STEVAL-ISA181V1

12 V / 600 mA flyback converter with Zero Power remote control



STEVAL-ISA184V1 5 V/1.2 A .12 V/750 mA

5 V/1.2 A ,12 V/750 mA double output flyback converter

Non Isolated Auxiliary SMPS

In a number of applications the reference of the secondary circuit is connected to the same reference as the primary – the AC mains. In such cases, an off-line non-isolated auxiliary power supply can be used to provide a regulated DC voltage using an inductor or low-cost transformer – with simplified isolation – as an energy transfer element by modulating the power supply's duty-cycle.

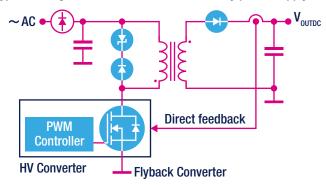
A buck — step-down — topology can be used to generate a positive output with respect to the common terminal and a buck-boost when the output voltage needs to be negative. A non-isolated flyback converter is the alternative when a higher output power is required.

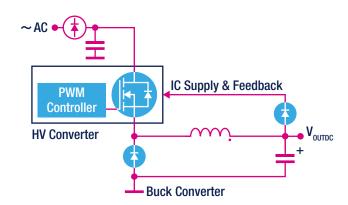
ST'S RECOMMENDED PRODUCTS FOR NON-ISOLATED AUXILIARY SMPS

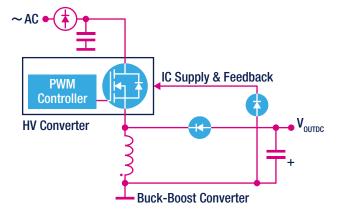
	HV converters	VIPER Protection	Clamping diodes	Output diodes	LD0
Buck				600 V Ultrafast STTH*06	
Buck-boost	VIPer0P VIPer*1			800 V to 1200 V Ultrafast STTH*08 STTH*10	Low Dropout (LDO) Linear Regulators
Non-isolated flyback	VIPer*6 VIPer122	SMA6F, SMB15F series	600 V Ultrafast STTH*06 800 V to 1200 V Ultrafast STTH*08 STTH*10 STTH*12	Schottky, FERD STPS* FERD*45, FERD*50, FERD*60, FER*100	LDF, LDFM, LDK220, LDK320, LDL212

Note: * is used as a wildcard character for related part number

Typical configurations for non isolated auxiliary power supply







MAIN EVALUATION BOARDS STEVAL-ISA115V1 12 V, 150 mA buck converter STEVAL-ISA178V1 5 V / 0.2 A buck converter STEVAL-ISA195V1 5 V / 0.36 A buck converter STEVAL-ISA196V1 5 V / 1.2 A non-isolated flyback converter

Smart Chargers and Adapters

Today, many device charging technologies and standards designed to ensure interoperability and improve convenience and ease of use are available, including wireless charging, quick charge and USB Type-C and Power Delivery.

ST can help engineers design charging solutions that meet requirements set by the mainstream standards — as well as proprietary charging protocols — with innovative converter architectures enabling best-in-class energy efficiency and power density as well as ensuring the lowest possible stand-by power.

USB Type-C™ PD Adapters and Quick Chargers

The new slim and reversible USB Type-CTM connector with USB Power Delivery (PD) feature provides up to 100 W (20 V, 5 A) enabling a faster and more efficient charging solution. Having considerably expanded the capability of USB devices, these connectors are now widely found in wall charge.

considerably expanded the capability of USB devices, these connectors are now widely found in wall chargers and adapters.

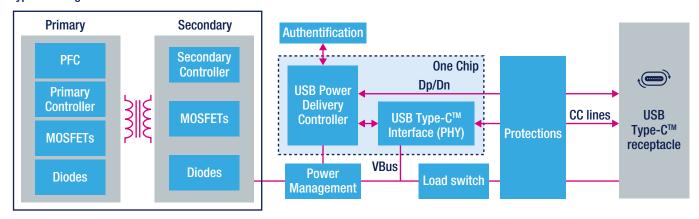
Designers of USB Type-CTM and Power Delivery compliant adapters and wall chargers can benefit from stand-alone controllers, from STM32 microcontrollers and their associated protocol stack, our STSAFE secure element as well as a specifically developed range of protection and filtering devices.

ST'S RECOMMENDED PRODUCTS FOR USB TYPE-C POWER DELIVERY SUBSYSTEM

Турс	Type-C and USB-PD Controllers				Protections							
Progran	mmable Solutions		Authencitcation		High surge	Single and multi lines	Type C Port Protection					
MCUs	Type-C Controller/ interface	Auto-Run Solutions	& Secure MCUs	Vrm current compact Co		protection for MCUs Communication Channel (CC) and Side Band Use (SBU)	Over voltage protection for USB-C and PD 3.0 controllers	LD0				
STM32G0,	STM32G0, STM32G4, STM32L5			20 V	ESDA25P35-1U1M ESDA24P140-1U1M	ESDL20-1BF4 ESDA25W		ST715				
СТМООГО		STUSB1700 STUSB4700					STSAFE-A	15 V	ESDA17P100-1U2M ESDA15P50-1U1M	ESDA17P20-1U1M	TCPP01-M12	LDK320
STM32F0 STM32F3	STHSB1602A	STUSB4710		9 V	ESDA13P70-1U1M	ESDL121-1BU2		Load Switch				
STIVISZES		STUSB4761		5 V	ESDA7P120-1U1M	ESDZV053-1BU2 ESD051-1F4		STELPD01*				

Note: * available. in Q3 2019

Typical configuration



MAIN EVALUATION BOARDS AND REFERENCE DESIGNS



45 W USB Type-C[™] Power Delivery 3.0 adapter reference design



STM32G0 world's 1st USB PD 3.0 MCU and its full ecosystem

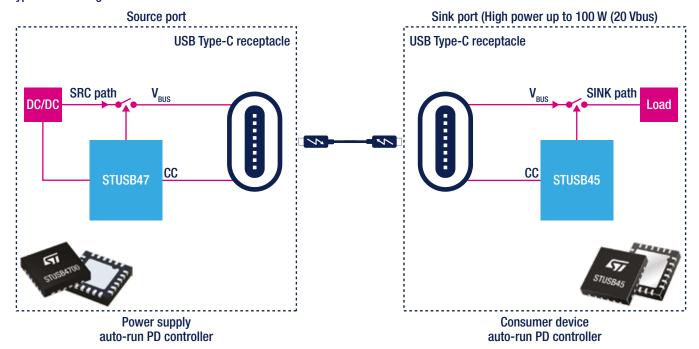


STEVAL-SMACH15V1 15 W 5 V output USB adapter evaluation board



USB Type-C[™] to DisplayPort[™] adapter

Typical block diagram with certified source and sink auto-run controllers



MAIN EVALUATION BOARDS AND REFERENCE DESIGNS



STEVAL-ISC004V1

STUSB4710A USB Power Delivery controller evaluation board (with on-board DC-DC)



STEVAL-ISC005V1

STUSB4500 USB Power Delivery controller evaluation board



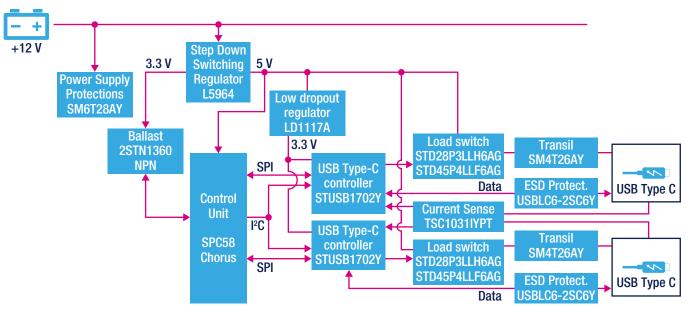
EVAL-SCS001V1 STUSB4500 reference



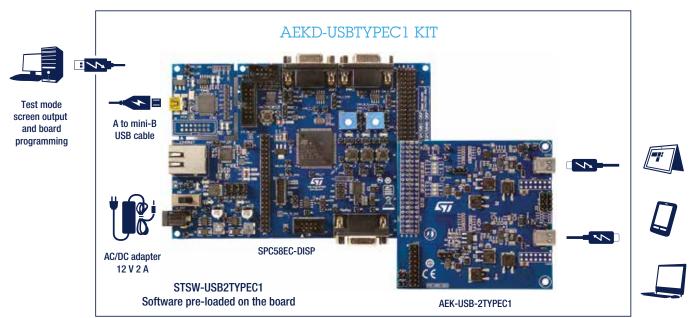
Automotive-grade USB Type-C and Power Delivery solution

The USB Type-C and USB Power Delivery specifications allow smarter connectivity with fewer cables, less connectors and universal chargers. The Type-C connector supports all the features of previous standards, and ports can be configured to only supply power in a Provider role, only sink power in a Consumer role, or be able to switch between both in a Dual role. Both data and power roles can be independently and dynamically swapped using the USB Power Delivery protocol. Most of the automotive applications require support for the Provider role only. When a USB device is connected, the Provider and the device (Consumer) negotiate a contract for the power objects through configuration channels.

Typical Block Diagram for Automotive grade USB Power Delivery



MAIN EVALUATION TOOLS



Note: AEK-POW-L5964V1 power supply board coming soon

Adapters for Tablets, Notebook and AIO

Power AC-DC adapters for notebooks and tablets need to be as small, thin and lightweight as possible while providing ultra-low stand-by power with high efficiency at all load conditions and excellent EMI performance.

A typical high-efficiency design includes a power factor corrector (PFC) working in transition mode (TM) followed by a fly-back, or half-bridge LLC resonant stage. For low power applications (<75 W), the mainstream architecture is based on a single stage flyback converter.

ST offers a broad range of high-voltage MDmesh™ and low-voltage STripFET power MOSFETs as well as standard and field-effect rectifiers (FERD). Our offer also includes a range of PFC, PWM primary controllers, synchronous rectification controllers, and single-chip analog and digital combo controllers.

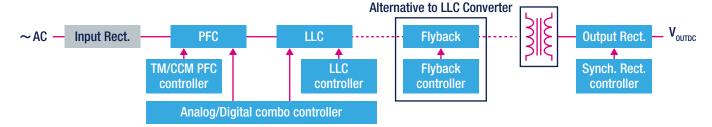


ST'S RECOMMENDED PRODUCTS FOR TABLETS, NOTEBOOK AND AIO ADAPTERS

	Controllers	Power MOSFETs	Diodes & Discretes	
PFC Block	TM Analog Controllers L6562A*, L6563*, L6564* CCM Analog Controllers L4981*, L4984D	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 650 V MDmesh M5 ST*65M5	600 V Ultrafast for TM STTH*L06, STTH*06, STTH15AC06* 600 V Ultrafast for CCM STTH*R06, STTH*T06	
	Converters & Controllers	Power MOSFETs	Diodes & Discretes	Voltage Reference, CC/CV Ctrl
	HV Converters for Flyback VIPerPlus SSR: VIPer*5, VIPer*7, VIPer*8 PSR: VIPer0P, VIPer*1, VIPer122 VIPer*6, ALTAIR*	800 V to 950 V MDmesh K5 ST*80K5, ST*9*K5 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP	Output Diodes for Flyback Schottky, FERD, STPS*, FERD*45, FERD*50, FERD*60, FERD*100	Voltage Reference T*431, T*432 Voltage and Current Ctrl TSM*, SEA*
	Flyback Controllers	•	Clamping Diodes for Flyback	Post Regulation
Isolation Stage	STCH02, STCH03, L6566A, L6566B, L6565 PFC & LLC Combo Controllers STCMB1, STNRG011	600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2	600 V to 1000 V Ultrafast STTH*06, STTH*08, STTH*10 Output Diodes for LLC Schottky, FERD	DC-DC Converters ST1S*, ST1S40, ST1S50
	LLC Analog Controllers L6599*, L6699 SR Analog Controllers SRK1000, SRK1001 for Flyback SRK2000A, SRK2001, SRK2001A for LLC	600 V MDmesh DM6 ST*60DM6 40 V-100 V STripFET F7 ST*N4F7, ST*N6F7, ST*N8F7, ST*N10F7	STPS* FERD*45, FERD*50, FERD*60, FERD*100 MOSFET protection for Flyback SMA6F, SMB15F series	Low Dropout (LDO) Linear Regulators ST715 LDK320

Note: * is used as a wildcard character for related part number

Typical Block Diagram with PFC Front-End



MAIN EVALUATION BOARDS AND REFERENCE DESIGNS



STEVAL-ISA170V1

12 V - 150 W resonant converter with synchronous rectification



EVLCMB1-90WADP

19 V - 90 W adapter based on TM PFC and HB LLC analog combo controller



EVLSTNRG011-150

12 V - 150 W power supply based TM PFC and HB LLC digital combo controller



EVLCMB1-AIO210W

12 V - 210 W adapter based on TM PFC and HB LLC analog combo controller

Wireless Charging

Wireless chargers are expected to become ubiquitous in hotels, airports, cafes and other public places as they enable to top up the batteries of portable and wearable devices, letting the user forget about cables.

In a wireless battery charging system, power is transferred by electromagnetic induction (inductive power transfer) between a transmitting pad - or dongle (TX) - and the battery-powered device (RX), such as a smartphone, smartwatch or sports gear. The power transmitter unit controls the current in the transmitting coil to transfer the correct amount of power as required by the receiver unit that continuously provides this information to the transmitter by modulating the transmitter carrier frequency through controlled resistive or capacitive load



insertion. Generating the correct amount of power guarantees the highest level of end-to-end energy efficiency and helps limit the device's operating temperature.

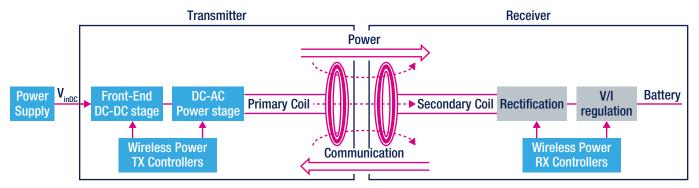
We have a range of wireless battery charging solutions including transmitters and receivers providing low stand-by power and foreign objects detection (FOD) feature. In order to prevent unwanted damage to any NFC Cards that might be close to the wireless charging source during operation, it is recommended to add an NFC Reader. The NFC Reader is able to detect the presence of the NFC Card or Tag (ST Reader ICs can detect Type A, B, F, or V NFC Cards), and therefore instruct the operating system to stop transmitting power. ST also offers evaluation and development tools and reference designs to help develop high-efficiency and compact wireless chargers that are Qi compliant.

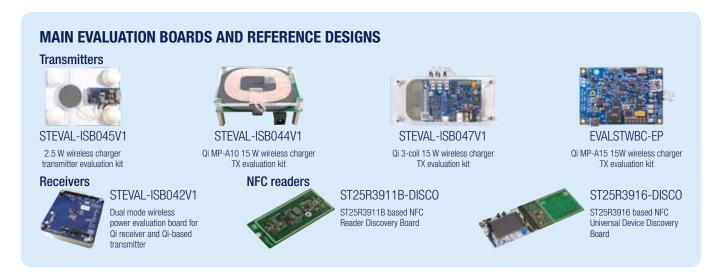
ST'S RECOMMENDED PRODUCTS FOR WIRELESS CHARGING

	Wireless charging controllers, MCUs	Gate drivers	Power MOSFETs	Protections	Diodes	NFC reader
Transmitte	STWBC, STWBC-EP, STWBC-MC, STWBC-WA, STM32F0, STM32F334, STM32G4	L6743B	STL10N3LLH5, STL8DN6LF3, ST*N2VH5, STL8DN10LF3, STL6N3LLH6, STL10N3LLH5		STPS*L30 STPS*45/60/100 FERD*45/60/100	ST25R3911B ST25R3912 ST25R3913 ST25R3916
Receiver	STWLC33, STM32F0			SMM4F, SMA6F series	BAT30F4, BAR46	

Note: * is used as a wildcard character for related part number

Typical Block Diagram





Desktop PCs Power Supply

The requirements for the standard ATX PC power market are a small form factor with better performance.

An intelligent control scheme that enables the adaption of load variation to minimize power consumption, together with optimized power semiconductors, is the key in meeting market demands. The smart analog and digital controllers, such as the STCMB1 and the STNRG011, the high-voltage MDmesh™ MOSFETs used for the PFC and DC-DC stages, the low-voltage STripFET MOSFETs for synchronous rectification, and SiC diodes (STPSC*) help designers develop the best PC power supply solutions to improve efficiency. ST's DC-DC converters guarantee high power density for the post-regulation.

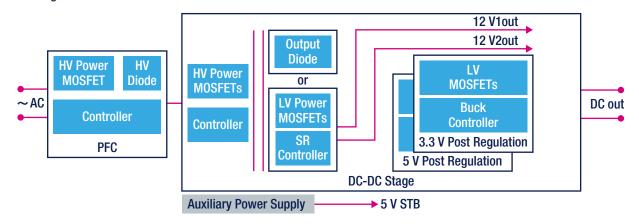


ST'S RECOMMENDED PRODUCTS FOR DESKTOP PC'S POWER SUPPLY

		Controllers	Power MOSFETs	Diodes & Discretes	Opamp V/I Sensing	
		TM Analog Controllers L6562A*, L6563*, L6564*	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP	600 V Ultrafast for TM STTH*L06, STTH*06, STTH15AC06*	Precision Op Amps (<50 MHz) TS*, TSV*, LMV*	
PFC	Block	CCM Analog Controllers L4981*, L4984D	600 V-650 V MDmesh M6 ST*60M6, ST*65M6	600 V Ultrafast for CCM STTH*R06, STTH*T06	MOSFET and IGBT Gate Drivers Multiple LS Gate Drivers PM8834	
		MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STNRG, STNRGPF01, STNRGPF12	650 V MDmesh M5 ST*65M5	SiC Diodes STPSC*065	Single LS Gate Drivers PM88*1	
		Controllers	Power MOSFETs	Diodes	E-Fuse	
		PFC & LLC Combo Controllers STCMB1, STNRG011	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP	Output Diodes Schottky, FERD STPS* FERD*45, FERD*50, FERD*60,	STEF01 STEF05	
		LLC Analog Controllers	600 V-650 V MDmesh M6	FERD*100	STEF12	
		L6599*, L6699	ST*60M6, ST*65M6	Voltage Reference	MOSFET and IGBT Gate Drivers	
Isola	tion	Asymmetrical HB Controllers L6591	600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2	T*431, T*432	HV HB Gate Drivers L649*	
DC-D	OC Stage		<i>'</i>	LD0	2043	
		MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STNRG	600 V MDmesh DM6 ST*60DM6 40 V-100 V STripFET F7	Low Dropout (LDO) Linear Regulators	Isolated Gate Drivers STGAP*	
		SR Analog Controllers SRK2000A, SRK2001, SRK2001A for LLC	ST*N4F7, ST*N6F7, ST*N8F7, ST*N10F7	LDF, LDFM, LDK320, LDL212	SR Multiple LS Gate Drivers PM8834	
		Controllers	Power MOSFETs			
Post Regu	ılation	L6726A, L673*, PM6680	STL90N3LLH6			

Note: * is used as a wildcard character for related part number

Typical configuration



MAIN EVALUATION BOARDS AND REFERENCE DESIGNS





Server & Telecom Power

AC-DC PSU & DC-DC power distribution

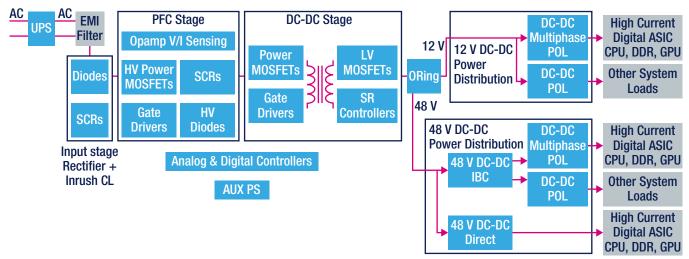
Data centers house thousands of servers, usually built in very dense network farms. Data center power requirements are constantly increasing and traditional power systems are no longer sufficient to meet this growing demand. The power distribution chain, from the frontend AC-DC stage to the backend DC-DC power distribution, needs to deliver the best performance in term of efficiency, power density and ability to interface with the digital world.

In telecom system power, the use of complex digital ASICs for managing growing data traffic is pushing further the power envelope. Telecom power management systems have to be highly energy-efficient and very dense to deliver the required high levels of power, while maintaining reasonable power consumption.

ST offers an extensive product and solution coverage to ensure the most optimized power design across all the distribution chain. Our digital and analog controllers combined with MOSFETs and drivers are key ingredients for implementing the most efficient and most dense AC-DC power delivery. On the backend DC-DC power distribution, ST offers advanced solutions for the Point-of-Load conversion and a recently developed innovative DC-DC conversion from the 48 V DC supply.



Typical Block Diagram for Server PSU





ST'S PRODUCT OFFERING FOR SERVER AND TELECOM AC-DC PSU

		SCRs	Diodes & Discretes	
Input Stage (Rect. & inrush current limiter)		High Temp. SCR	Bridge Rectifier Diodes STBR*12	
	Controllers	TN*015H-6, TN*050H-8, TN*050H-12W	Diodes & Discretes	MOSFET and IGBT Gate Drivers
PFC Block	CCM Analog Controllers L4981*, L4984D MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4,	High Temp. SCR TN*050H-12W Power MOSFETs 600 V-650 V MDmesh M2 ST*60M2, ST*65M2 600 V-650 V MDmesh M6	600 V Ultrafast for CCM STTH*R06 STTH*T06 STTH*L06 SiC Diodes STPSC*065	HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1
	STNRG, STNRGPF01, STNRGPF12	ST*60M6, ST*65M6	Opamp V/I Sensing	E-Fuse
		650 V MDmesh M5 ST*65M5 SiC MOSFETs SCT*N65G2	Precision Op Amps (<50 MHz) TS*, TSV*, LMV*	
	Controllers	Power MOSFETs	Diodes	STEF01
	LLC Analog Controllers L6599A, L6699	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh M6 ST*60M6, ST*65M6	Output Diodes for LLC Schottky, FERD STPS* FERD*45, FERD*50, FERD*60	STEF05 STEF12
	Asym. HB	600 V-650 V MDmesh DM2	LDO	MOSFET and IGBT Gate Drivers
Isolation DC-DC Stage	Analog Controllers L6591 MCUs & Digital Controllers STM32F334, STM32G4,STNRG SR Analog Controllers SRK2000A, SRK2001, SRK2001A	ST*60DM2, ST*65DM2 600 V MDmesh DM6 ST*60DM6 SR 60 V-100 V STripFET F7 ST*N6F7 ST*N8F7 ST*N10F7	Low Dropout (LDO) Linear Regulators LDF, LDFM, LD39050, LD39100, LD39200, LDL112, LDL212, LD59100	HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* SR Multiple LS Gate Drivers PM8834 SR HV HB Gate Drivers L649*

Note: * is used as a wildcard character for related part number

MAIN EVALUATION BOARDS AND REFERENCE DESIGNS



STEVAL-ISA147V3

500 W fully digital AC-DC power supply (D-SMPS)



STEVAL-ISA172V2

2 kW fully digital AC-DC power supply (D-SMPS)



EVLSTNRG-1kW

1 kW SMPS digitally controlled multi-phase interleaved converter



STEVAL-IPFC12V1

2 kW two-channel digitally controlled interleaved PFC with digital inrush current limiter



STEVAL-IPFC01V1

3 kW three-channel digitally controlled interleaved PFC



STEVAL-DPSLLCK1

3 kW Full Bridge LLC resonant digital power supply evaluation kit

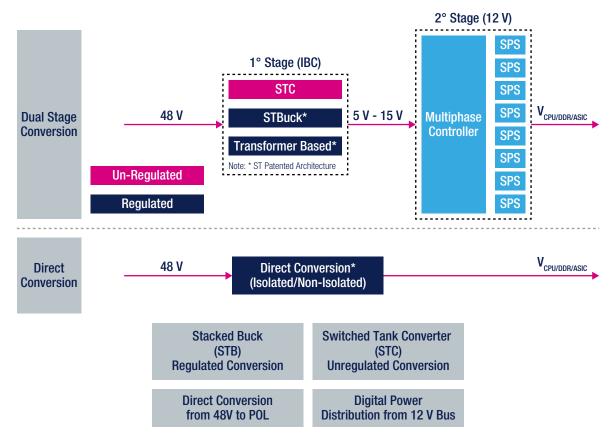
Power Distribution for Modern Data Center

To support the evolution and expansion of Cloud services, the Internet of Things and mobile apps, the demand for data centers is growing exponentially with more powerful CPUs and extended memory banks making efficiency and power density a daunting challenge along with enhanced reliability. In a typical architecture, a 48 V DC rail is generated from the AC-DC power supply unit that will then be converted to provide the number of DC rails needed to supply the variety of loads and circuits in the server. This conversion must meet stringent efficiency targets requiring innovative architectures like those developed by the Power Stamp Alliance (PSA) for direct conversion from the 48 V rail. Innovative power distributions architectures include also 48 V to 12 V intermediate bus converters, both in regulated and unregulated version.

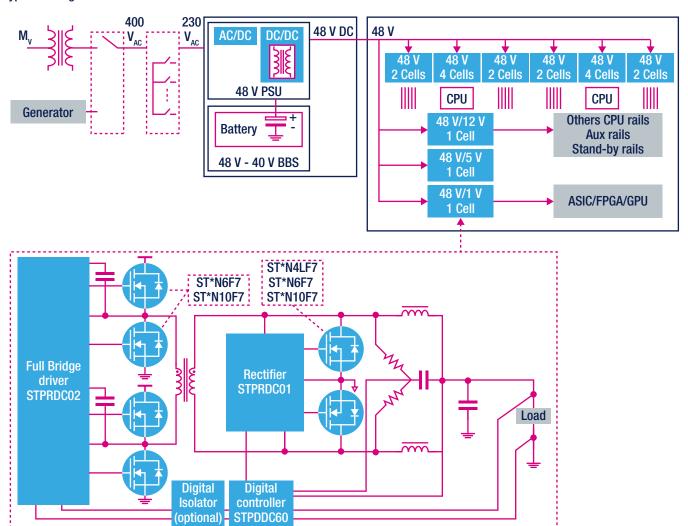


We offer a range of high-efficiency DC-DC conversion solutions including an isolated, single-stage direct 48 V to the Point-of-Load (PoL) resonant, conversion solution for CPUs and DDR memories based on the Power Stamp Alliance (PSA) product footprint and compliant with Intel VR13 and VR12.5 specifications. We support also hybrid architectures where the transition to 48 V is implemented though intermediate 12 V conversion, with innovative high efficiency solutions.

Power Delivery for Modern Data Center

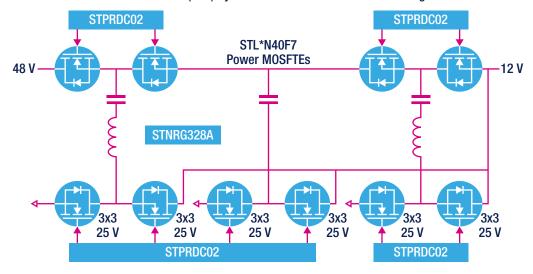


Typical Configuration for 48 V Isolated Direct Conversion

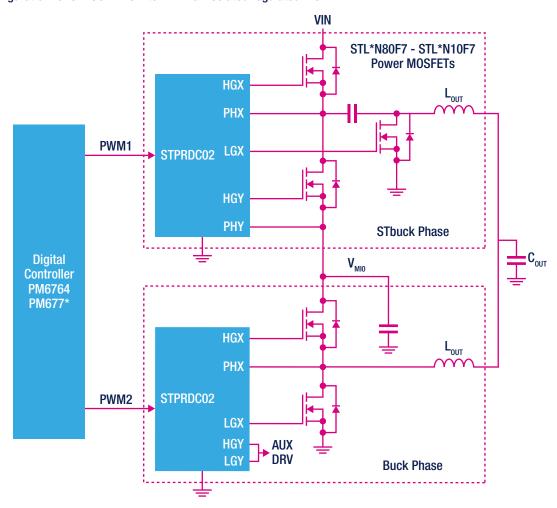




Typical Configuration for Switched-Tank Converter (STC) System - 48 V to 12 V non isolated unregulated IBC



Typical Configuration for STBUCK - 48 V to 12 V non isolated regulated IBC



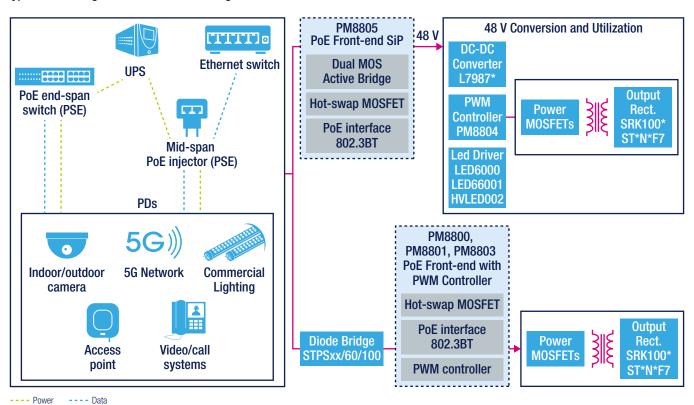
Power over Ethernet (PoE)

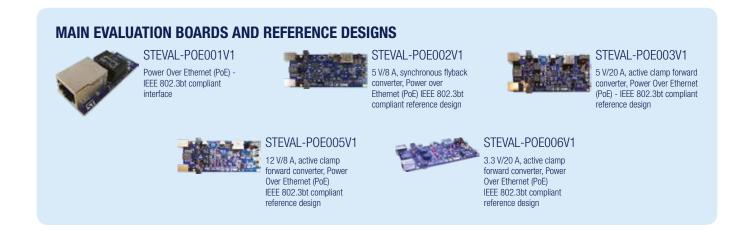
Power over Ethernet (PoE) is a widely adopted technology used to transfer power and supply the powered device (PD) including wireless access points, VoIP phones over an RJ-45 cable also carrying data as described in the IEEE 802.3 standard and its evolutions including IEEE 802.3bt, IEEE 802.3at and IEEE 802.3af.

We offer a range of products providing a complete interface with all the functions required by the communication standard, including detection and classification as well as protection features such as under-voltage lockout (UVLO) and in-rush current limitation. In addition, these products can control hot-swap power MOSFETs that can greatly simplify the development of IEEE 802.3 compliant solutions for powered devices (PD).



Typical block biagram for PoE Power Management





LED TV Power Supply

In addition to their outstanding image quality, new generation TVs gain attention for their slim silhouette and high energy efficiency, for which the TV's power supply is a key factor. The power supply unit (PSU) requires a low profile to maintain the TV's slim appearance and advanced silicon devices to ensure high efficiency.

To achieve these stringent requirements, PSUs typically have a Power Factor Corrector (PFC) stage and use advanced topologies, like half-bridge LLC (HB-LLC) resonant.

ST offers a broad portfolio of high-voltage MDmeshTM and low-voltage STripFETTM power MOSFETs, field-effect rectifier diodes (FERD), Schottky and Ultrafast diodes, a full range of protection ICs as well as dedicated analog and digital switching controllers who allow avoiding the auxiliary power thanks to a very low consumption at no load, and STM32 microcontrollers to enable developers to exploit the full potential of digital PSU implementations.

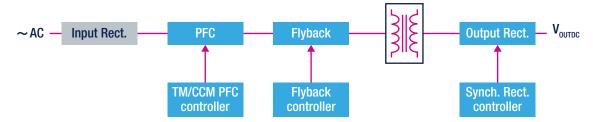


ST'S RECOMMENDED PRODUCTS FOR LED TV POWER SUPPLY

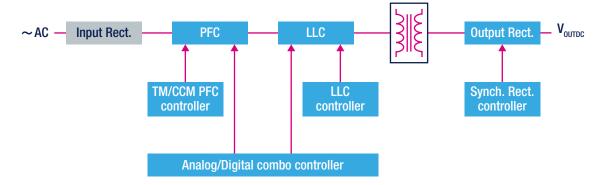
	Controllers	Power MOSFETs	Diodes & Discretes	Opamp V/I Sensing
	TM Analog Controllers L6562A*, L6563*, L6564* CCM Analog Controllers	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP	600 V Ultrafast for TM STTH*L06 STTH*06 STTH15AC06*	Precision Op Amps (<50 MHz) TS*, TSV*, LMV*
PFC Block	L4981*, L4984D	600 V-650 V MDmesh M6 ST*60M6, ST*65M6 650 V MDmesh M5	600 V Ultrafast for CCM STTH*R06 STTH*T06	MOSFET and IGBT Gate Drivers
	MCUs & Digital Controllers STM32F0, STM32G0,			Multiple LS Gate Drivers PM8834
	STM32F301, STM32F334, STM32G4, STNRG, STNRGPF01, STNRGPF12	ST*65M5	SiC Diodes STPSC*065	Single LS Gate Drivers PM88*1
	Controllers	Power MOSFETs	Diodes & Discretes	MOSFET and IGBT Gate Drivers
Isolation Stage	Flyback Controllers L6566A, L6566B, L6565, L6668, STCH02, STCH03 PFC & LLC Combo Controllers STCMB1, STNRG011 LLC Analog Controllers L6599*, L6699 Asymmetrical HB Controllers L6591 MCUs & Digital Controllers STM32F0, STM32F301, STM32F334, STM32G4, STNRG SR Analog Controllers SRK1000, SRK1001 for Flyback SRK2000A, SRK2001, SRK2001A	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 600 V MDmesh DM6 ST*60DM6 60 V-100 V STripFET F7 ST*N6F7 ST*N8F7 ST*N10F7	Output Diodes for Flyback Schottky, FERD, Ultrafast STPS*, FERD*, STTH* Clamping Diodes for Flyback 600 V to 1000 V Ultrafast STTH*06, STTH*08, STTH*10 Output Diodes for LLC Schottky, FERD STPS* FERD*45, FERD*50, FERD*60, FERD*100 MOSFET protection for Flyback SMA6F, SMB15F series Voltage Reference	HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* SR Multiple LS Gate Drivers PM8834 SR HV HB Gate Drivers L649* DC-DC Conversion ST1S12, ST1S3*, ST1S4*, ST1S50

Note: * is used as a wildcard character for related part number

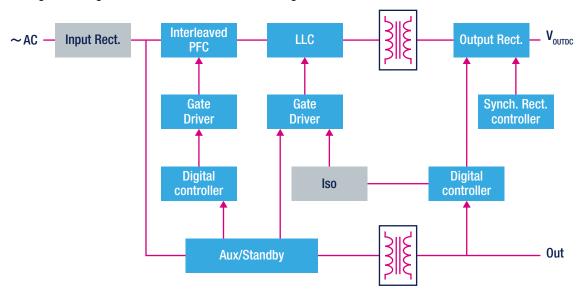
Typical Block Diagram for Analog Control Solutions for Small Pannel Size



Typical Block Diagram: Analog Control Solutions with no Aux supply, for Small/Medium Panel Size



Typical Block Diagram for Digital Control Solutions for Medium/Large Panel Size



MAIN EVALUATION BOARDS AND REFERENCE DESIGNS



EVL185W-LEDTV

185 W power supply with PFC and standby supply for LED TV



EVLCMB1-90WADP

19 V - 90 W adapter based on TM PFC and HB LLC analog combo controller



EVLSTNRG011-150

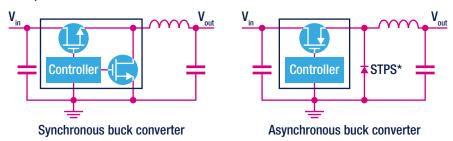
12 V - 150 W power supply based on TM PFC and HB LLC digital combo controller

DC-DC Conversion

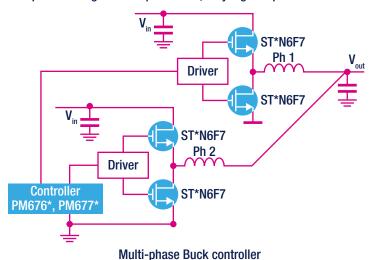
A DC-DC switching converter is used to locally supply any component or part of a system with the desired DC voltage and current. Depending on the application's relationship between the input and output voltage, engineers have to choose the best power topology — buck, boost, buckboost or inverting, with or without synchronous rectification. In addition, they can decide to use an implementation based on monolithic ICs or with discrete power switches and controllers — or even an advanced digital implementation. Whatever their choice, the right semiconductor products are key to meet their specific efficiency and size design targets.

ST's broad product portfolio includes highly-integrated DC-DC converters and PWM controllers, power MOSFETs and rectifiers, protection ICs, linear voltage regulators, to address a wide range of topologies and power requirements. We also provide a comprehensive range of hardware and software evaluation and development tools including our eDesignSuite that helps engineers design high-efficiency DC to DC converters.

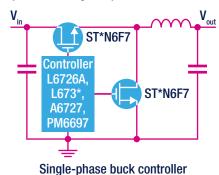
Typical buck configuration: up to 61 Vin/3 A lout



Typical multi-phase configuration: up to 12 Vin, very high output current



Typical single phase discrete configuration: up to 18 Vin, high output current



Note: * is used as a wildcard character for related part number

MAIN EVALUATION BOARDS AND REFERENCE DESIGNS



Asynch. buck up to 60 Vin, 3.3 Vout - 3 A lout



STEVAL-ISA159V1

Synch. Buck 36 Vin, 3.3 Vout - 400 mA



STEVAL-ISA160V

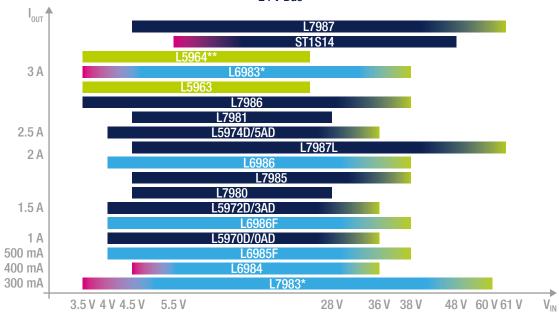
Synch. Buck 3.3 Vin, 1.2 Vout-3 A lout, Auto. Grade



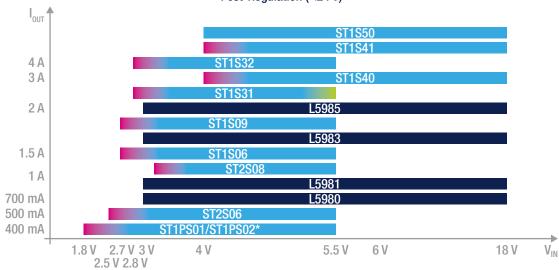
STEVAL-ISA205V1

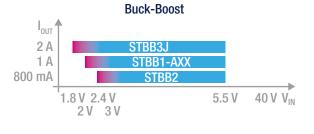
Synch. Buck 12 Vin, 3.3 Vout-2 A lout, Auto. Grade

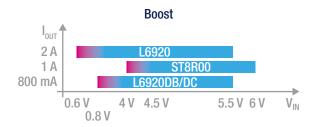




Post-Regulation (<24 V)



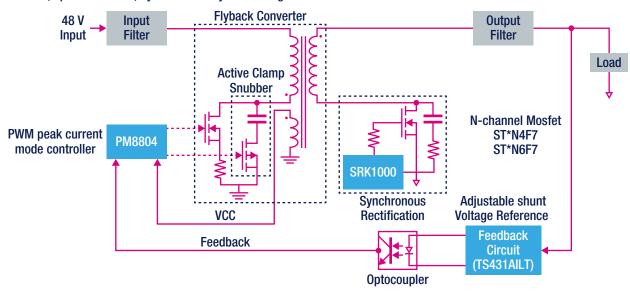




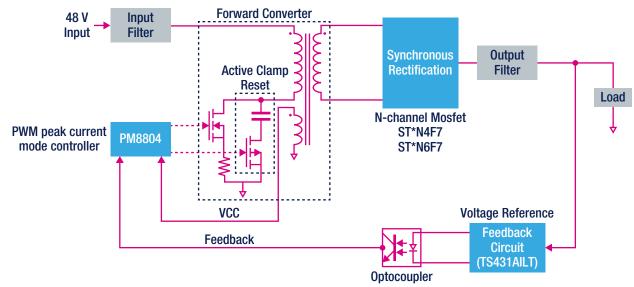
Asynchronous Automotive Synchronous Compact BOM

Note: * full production in H2 2019 *** dual, parallel up to 7A

Typical 48 Vin, up to 65 W Pout, Synchronous Flyback configuration



Typical 48 Vin, > 65 W Pout, Active Clamp Forward configuration



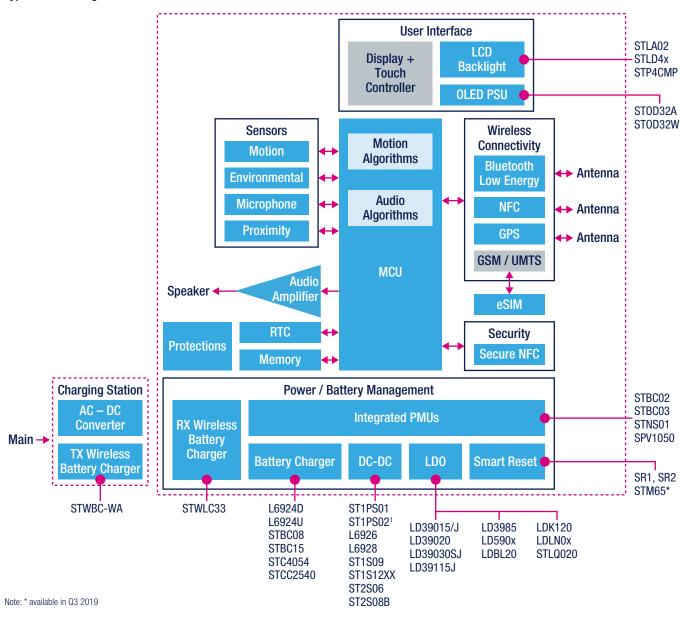


WEARABLE DEVICES - POWER MANAGEMENT

Wearable devices, by their very nature, must be compact and comfortable for the user. They need to deliver precise information about the user states and conditions, have low power consumption and the right level performance to make them convenient and easy to use. ST's products for wearable devices are designed to meet the needs of the most demanding systems with a portfolio covering the needs of developers of smart watches, fitness trackers, heart-rate monitors, sports equipment and a variety of other wearable devices. Our portfolio includes digital processing, sensors, connectivity, security and power management solutions that can make the difference in a challenging and competitive market.

Specifically for power management, ST provides a range of solutions to match the needs of very small form factor with outstanding efficiency performance and longer battery life.

Typical Block Diagram of Smart Watch



MAIN EVALUATION BOARDS



STEVAL-1PS01AJR/1PS01EJR/ 1PS01BJR*/1PS01GJR*

Evaluation board based on the ST1PS01EJR 400 mA nano-quiescent synchronous step-down converter

Note: * available in Q3 2019



STEVAL-LD0001V1

Quad high performance LDO evaluation board based on LDBL20, LDLN025, LD39130S and STLQ020

LED LIGHTING AND CONTROLS

LED General Illumination

LED lamps and bulbs can have a number of different form-factors depending on the specific use, size and dimension of the application, including retrofit bulbs, high-bay lights, low-bay lights, emergency lights. Driving a string of LEDs has to do with AC-DC and DC-DC conversion — designed using non-isolated, isolated, single stage or multi-stage topologies — that has to ensure high efficiency and reliability obtained at a competitive cost point.

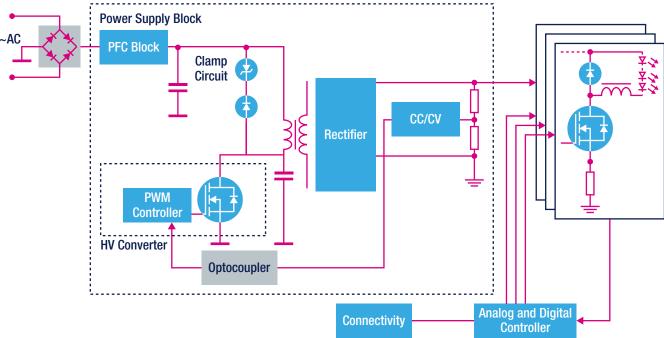
Modern applications include a range of connectivity features to implement remote monitoring and control, making the LED lighting a pillar of the smart home, smart building and smart city environment.

We have a range of pulse-width modulation (PWM) and power factor correction (PFC) controllers, power MOSFETs and diodes as well as a comprehensive set of hardware evaluation and development tools including reference designs to help developers design high-efficiency LED lighting solutions.

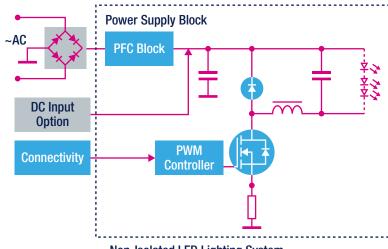


Typical Block Diagram

LED General Illumination



Isolated LED Lighting System



Non-Isolated LED Lighting System

ST'S PRODUCT OFFERING FOR LED GENERAL ILLUMINATION

			Dower MOCETTo		D: 1 0 D: 1	MODERT HORTOLD
	Controllers		Power MOSFET		Diodes & Discretes	MOSFET and IGBT Gate Drivers
PFC Block	TM Analog Controllers L6562*, L6563*, L6564* CCM Analog Controllers L4981*, L4984D MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STLUX, STNRG		600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 SiC MOSFET SCT*N65G2		600 V Ultrafast for TM STTH*L06, STTH*06, STTH15AC06* 600 V Ultrafast for CCM STTH*R06, STTH*T06 SiC Diodes STPSC*065	Single LS Gate Drivers PM88*1
	Controllers & Converters		Power MOSFET	s	Diodes & Discretes	Voltage Reference, CC/CV Ctrl
Isolation Stage	Offline LED Drivers HVLED001B, HVLED001A, HVLED00 HV Converters VIPer0P, VIPer*1, VIPer*6, VIPer122 VIPer*7, VIPer*8 LLC Analog Controllers L6599*, L6699 PFC & LLC/LCC Combo Controllers STCMB1, STNRG011 MCUs & Digital Controller STM32F0, STM32G0, STM32F301, S STM32G4, STM8S, STLUX, S' SR Analog Controllers SRK1000, SRK1001 for Flyb	s STM32F334, FNRG	800 V to 950 V MDmesh ST*80K5, ST*9*K5 5, 600 V-650 V MDmesh N ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh N ST*60M6, ST*65M6 600 V-650 V MDmesh D ST*60DM2, ST*65DM.		Output Diodes for Flyback Schottky, FERD, Ultrafast STPS*, FERD*, STTH* Clamping Diodes for Flyback 600 V to 1000 V Ultrafast STTH*06, STTH*08, STTH*10 Output Diodes for LLC/LCC Schottky, FERD STPS* FERD*45, FERD*50, FERD*60, FERD*100 MOSFET Protection for Flyback SMA6F, SMB15F series	Voltage Reference T*431, T*432
Multiple strings management	Offline LED Drivers HVLED002		600 V-650 V MDmes ST*60M2, ST*65N ST*60M2-EP 600 V-650 V MDmes ST*60M6, ST*65N STripFET F7 ST*N6F7, ST*N10	M2, sh M6 M6	Schottky Diodes STPS* FERD Diodes FERD* ≥ 200 V Ultrafast Diodes STTH* DC-DC LED Drivers LED5000, LED6000	HV HB Gate Drivers L649*, L6395 Single LS Gate Drivers PM88*1 Multiple LS Gate Drivers PM8834
	Bluetooth Low Energy (BLE)		Sub 1G	Hz RF
Wireless Connectivity	BLE 5.0 SoC BlueNRG-2 BLE 4.2 SoC BlueNRG-1 Baluns BALF-NRG-0*D3, BALF-NRG-02J5 Wireless MCUs BLE 5.0 STM32WB	Cer SPBTLI	tified Modules E-1S, SPBTLE-RF, PBTLE-RF0		Sub-1GHz transceivers S2-LP, SPIRIT1 MCUs 32F0, STM32G0, STM32L0 Baluns BALF-SPI-0*D3, BALF-SPI2-0*D3	Certified Modules SPSGRF (868 and 915 MHz) SPSGRFC (433, 868 and 915 MHz)

Note: * is used as a wildcard character for related part number

MAIN EVALUATION BOARDS



EVLHVLED815W15 15 W HPF LED driver with PSR



STEVAL-ILL083V1 10 W Smart home lighting with BLE



STEVAL-ILL069V2

35 W Analog power supply (CVout) for LED driving



STEVAL-ILL070V4

35 W, analog power supply (CC/CV) for single string led driver



STEVAL-ILL077V1 60 W, digital multiple-string LED driver



STEVAL-LLL004V1

75 W digitally controlled non isolated constant current LED driver

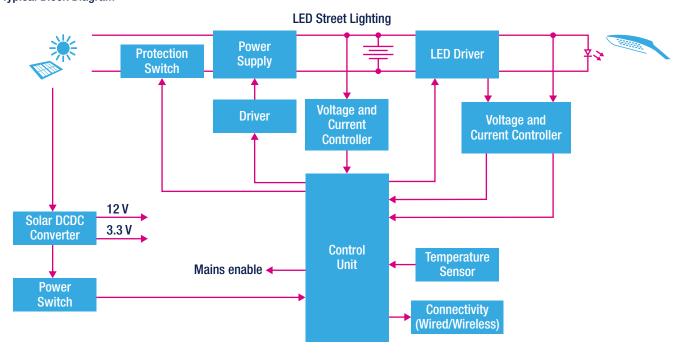
LED Street Lighting

Street lighting installations have evolved from basic energy-hungry illumination spots to central devices enabling a set of services, such as presence and traffic level monitoring and incident detection surveillance, while optimizing illumination levels to specific road and weather conditions to support administrations transforming cities in Smart Cities.

We have a broad range of wired and wireless connectivity, power management and LED driving solutions. A range of high-performance and low-power STM32 microcontrollers together with presence, proximity, camera and environmental sensors as well as MEMS microphones enable design of advanced street lighting systems.



Typical Block Diagram







STEVAL-ILL066V2

100 W LED street lighting with STLUX digital controller



STEVAL-ILL053V2

48 V - 130 W high efficiency converter with PFC for LED street lighting



STEVAL-ILL074V1/V2

60 W Analog power supply in QR/FOT mode (CVout) for LED driving



STEVAL-ILL085V1

70 W, analog power supply low THD (CC/CV) for led



STEVAL-LLL006V1*

75 W LED driver (CC/CV) with Sub 1GHz Connectivity



STEVAL-LLL004V1

75 W digitally controlled non isolated constant current LED driver



EVL150W-HVSL

150 V - 150 W LED driver featuring TM PFC and LCC resonant converter with STCMB1 combo controller



EVL6699-HVSL

150 V - 150 W LED driver featuring TM PFC and LCC resonant converter with



ST'S PRODUCT OFFERING FOR LED STREET LIGHTING

	Controllers	Power MOSFETs	Diodes & Discretes	MOSFET and IGBT Gate Drivers
Power Supply	TM PFC Analog Controllers L6562*, L6563*, L6564* CCM PFC Analog Controllers L4981*, L4984D Offline LED drivers HVLED001B, HVLED001A, HVLED007 PFC & LLC/LCC Combo Controllers STCMB1, STNRG011 LLC/LCC Controllers L6599A*, L6699 MCUs & Digital Controllers STM32F0, STM32G0, STM32F301, STM32F334, STM32G4, STLUX, STNRG SR Analog Controllers SRK1000, SRK1001 for Flyback SRK2000A, SRK2001, SRK2001A for LLC	800 V to 1050 V MDmesh K5 ST*80K5, ST*9*K5, ST*105K5 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 600 V MDmesh DM6 ST*60DM6 SiC MOSFET SCT*N65G2 60 V-100 V STripFET F7 ST*N6F7, ST*N8F7, ST*N10F7	600 V Ultrafast for TM PFC STTH*L06, STTH*06, STTH15AC06* 600 V Ultrafast for CCM PFC STTH*R06, STTH*T06 SiC Diodes STPSC*065 Output Diodes for Flyback Schottky, FERD, Ultrafast STPS*, FERD*, STTH* Clamping Diodes for Flyback 600 V to 1000 V Ultrafast STTH*06, STTH*08, STTH*10 Output Diodes for LLC/LCC Schottky, FERD STPS*, FERD*45, FERD*50, FERD*60, FERD*100 MOSFET Protection for Flyback SMA4F, SMB15F series	Single LS Gate Drivers PM88*1 Multiple LS Gate Drivers PM8834 HV HB Gate Drivers L649* Isolated Gate Drivers STGAP* Voltage Reference, CC/CV Ctrl Voltage Reference T*431, T*432 Voltage and Current Ctrl TSM*, SEA
	Controllers	DC-DC Buck LED Drivers	DC-DC Boost LED Drivers	LED Array Drivers
LED Driver	Offline LED drivers HVLED002	LED5000 LED6000	LED6001	STP04CM05, LED8102S
	Temperature Sensors	Control Unit	Protection Switch	Diodes and discretes
Sensing, Processing, Control, LED Bypass	STLM20 STTS751 LM135Z	MCUs STM32F0, STM32G0	60 V-100 V STripFET F7 ST*N6F7, ST*N8F7, ST*N10F7	LBP01
	Wired - Power Line Communication	Wireless - Sub 1 GHz RF	Wireless - Sigfox	Wireless - LoRA
Connectivity	Power Line Transceivers ST7570, ST7580, ST7590	Sub-1GHz transceivers S2-LP, SPIRIT1 MCUs STM32F0, STM32G0, STM32L0 Balun BALF-SPI-0*D3, BALF-SPI2-0*D3 Certified Modules SPSGRF (868 and 915 MHz) SPSGRFC (433, 868 and 915 MHz)	Sub-1GHz transceivers S2-LP MCUs STM32L0, STM32L4 Baluns BALF-SPI2-01D3 Embedded Software STSW-S2LP-SFX-DK Secure MCUs STSAFE-A100	MCUs STM32L0, STM32L1, STM32L4 Embedded Software I-CUBE-LRWAN Secure MCUs STSAFE-A100

Note: * is used as a wildcard character for related part number



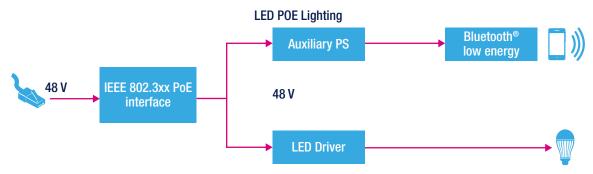
LED POE Lighting

Power over Ethernet (PoE) is a widely adopted technology used to supply a powered device (PD) over an RJ-45 cable while carrying data. Described in the IEEE 802.3 standard and its enhancements including IEEE 802.3bt, IEEE 802.3at and IEEE 802.3af, this technology is becoming attractive for LED lighting.

We have a range of products providing a complete interface with all the functions required by the communication standard including detection and classification, protection features such as under-voltage lockout (UVLO) and in-rush current limitation as well as the control of the hot-swap power MOSFETs that can greatly simplify the development of IEEE 802.3 compliant solutions for powered devices (PD). We also have high-efficiency, optimized DC-DC conversion solutions for supplying the LEDs.



Typical Block Diagram



ST'S PRODUCT OFFERING FOR LED POE LIGHTING

PoE Interface	Protections	Auxiliary Power Supply	LED	Driver
IEEE 802.3bt PM8805			Buck LED6000	60 V-100 V STripFET F7
IEEE 802.3at PM8803, PM8801	TVS for power rail surge protecion SMA4F, SMB15F	Buck L7987L	Boost LED6001	ST*N6F7, ST*N8F7, ST*N10F7 Schottky Diodes STPS*
IEEE 802.3af PM8800A			Inverse Buck HVLED002	

Note: * is used as a wildcard character for related part number





Lighting Controls

Lighting controls have evolved from simple triac dimmers to more sophisticated architectures including light sensors, digital and PWM dimmers, DALI network-based systems and wireless programming solutions.

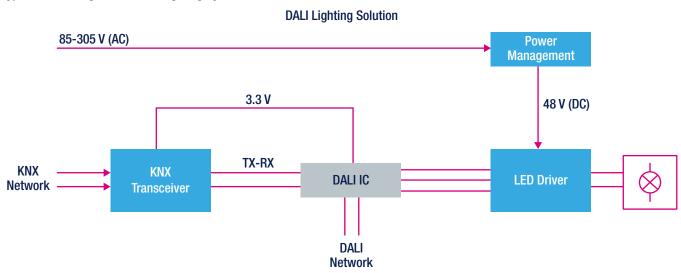
ST's long-term partnerships with major lighting suppliers combined with our leadership in discrete and integrated power devices enable us to offer high efficiency and cost-optimized solutions for all types of lighting applications and their control – both wired (e.g. Powerline) or wireless (RF) – for industrial, residential, commercial, and architectural lighting applications.

DALI Lighting Solution

Digital Addressable Lighting Interface (DALI) is a trademark for a network-based technology used to effectively control lighting in building automation. Originally defined in IEC 60929 standards, it's updated in IEC 62386 which includes LED device types.

We provide a range of analog and digital controllers including the STLUX family and the STM32 microcontrollers to implement the AC-DC and DC-DC power converter and run the DALI protocol.

Typical Block Diagram for DALI Lighting System



ST'S PRODUCT OFFERING FOR LIGHTING CONTROLS

LED Driver			Power Management	KNX Transceiver
Digital Controller STLUX Development Too STSW-STLUXLIBO STSW-STLUXSMED	ls 2,	MCUs STM32F1, STM32L1, STM8 Embedded Software STSW-DALI002, STSW-DALI001, STSW-STM8025	Refer to LED General Illumination section	STKNX

MAIN EVALUATION BOARDS





STEVAL-ILM001V1

Plug-in hardware module for the STM8S-DISCOVERY interface for

LED Wireless Programming

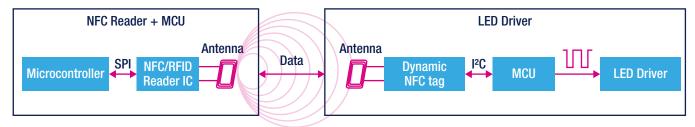
Today's smart LED bulbs let users control features including brightness and color. These properties are controlled though the driver and can be programmed and modified at any time during manufacturing, distribution, installation or maintenance.

The use of NFC technology enables wireless programming using a smartphone, tablet or portable RFID/NFC reader, without having to power up the LED driver, and brings enhanced flexibility and energy-savings in addition to reducing development time and cost.

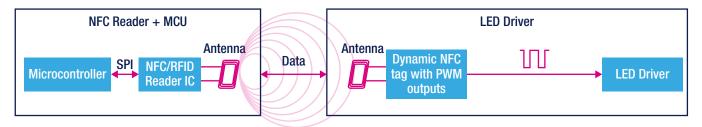
STMicroelectronics offers optimized and complete LED driver programming solutions with its comprehensive NFC portfolio, fully addressing the lighting market and featuring all the functions needed for wireless LED programming.

Typical Block Diagram of LED Wireless Programming

13.56 MHz electromagnetic field



High-end Market



Entry-level Market

ST'S PRODUCT OFFERING FOR LED WIRELESS PROGRAMMING

	NFC/RFID Reader IC	Microcontrollers		
NFC Reader + MCU	ST25R	STM8S STM32F0, STM32G0		
	Dynamic NFC Tag	MCUs and Digital Controllers	LED Driver	
LED Driver for high-end market	ST25DV-I ² C Series	STM8S STM32F0, STM32G0 STM32F3, STM32F334, STM32G4 STLUX	HVLED001*, HVLED002 LED600*, LED5000, LED2000 STP04/08/16/24	
	Dynamic NFC Tag with PWM Output		LED Driver	
LED Driver for entry-level market	ST25DV-PWM Series		HVLED001*, HVLED002 LED600*, LED5000, LED2000 STP04/08/16/24, LED12/16/24*, LED8102S	

Note: * is used as a wildcard character for related part number



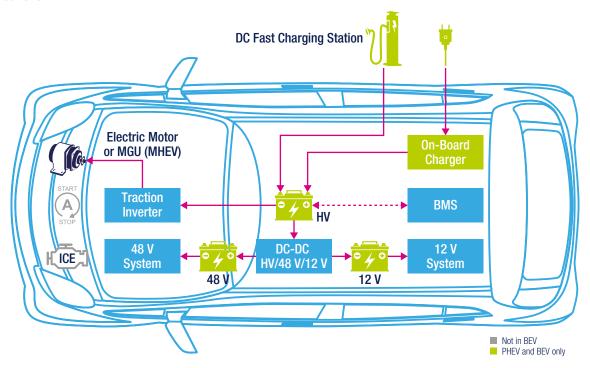






ELECTRO-MOBILITY

Key applications



SOLUTIONS

ST's key products and solutions for Electro-Mobility applications include:





HW & SF Development Tools - Sample Kits, Evaluation Kits, Product Selectors

FIND OUT MORE

www.st.com/electro-mobility

Battery Management System (BMS) Charging Station DC-DC Converter Electric 2-wheelers Electric Traction (Main Inverter) Mild Hybrid 48 V Systems On Board Charger (OBC)



Traction Main Inverter

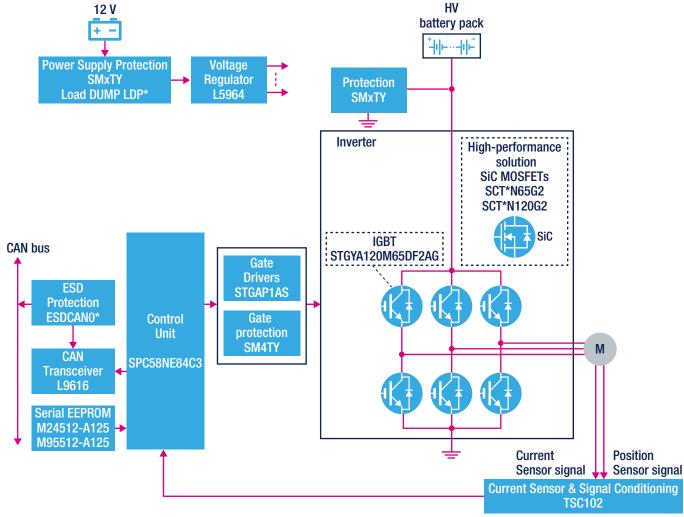
The traction inverter converts energy from the vehicle's battery to drive the electrical engine. This key component has a direct impact on road performance, driving range and reliability of the vehicle due to its generated power traction and its weight and size.

Subject to intense heat and vibration in the vehicle, these converters must be able to handle high power and currents along with associated Electro Magnetic Compatibility (EMC) challenges. Fail-safe operation needs to be assured to ensure reliability and safety for the driver and passengers.

To help developers increase the inverter's power efficiency and reduce size and weight, ST has a wide offer of discrete semiconductors including AEC-Q101 qualified silicon and siliconcarbide (SiC) MOSFETs and diodes as well as IGBTs. These are complemented by AEC-Q100 qualified galvanically isolated IGBT and MOSFET gate drivers and SPC5 32-bit automotive microcontrollers for implementing scalable, cost-effective and energy-efficient solutions.



Main Inverter



Note: * is used as a wildcard character for related part number

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www.st.com/main-inverter-electric-traction



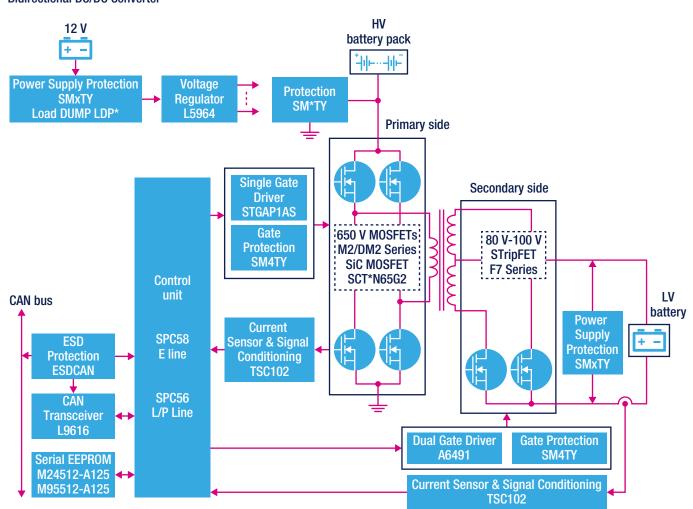
Bidirectional DC/DC Converter

Electric vehicles (EV) use two different power systems; a high-voltage battery (200 to 800 Vdc) for traction and a low-voltage (12/48V) one for supplying all the electric appliances in the vehicle. Traditionally, the low-voltage battery was charged from the alternator, but in today's vehicles it gets its power from the high-voltage battery pack. However, in specific electric car architectures, this low voltage battery should be ready to help recharge the high-voltage battery pack in order to provide energy for cranking the car. This means that the on-board DC-DC converter must be bi-directional and very efficient as well as highly reliable in order to run the complex control algorithms needed to ensure an energy-efficient solution.



ST has a wide offer of discrete semiconductors including AEC-Q101qualified silicon and silicon-carbide(SiC) MOSFETs and diodes as well as IGBTs. These are complemented by AEC-Q100 qualified galvanically isolated IGBT and MOSFET gate drivers and SPC5 32-bit automotive microcontrollersto enable scalable, cost-effective and energy-efficient solutions for implementing these challenging converters.

Bidirectional DC/DC Converter



Note: * is used as a wildcard character for related part number

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www.st.com/bidirectional-dc/dc-converter



48 V Start-Stop System

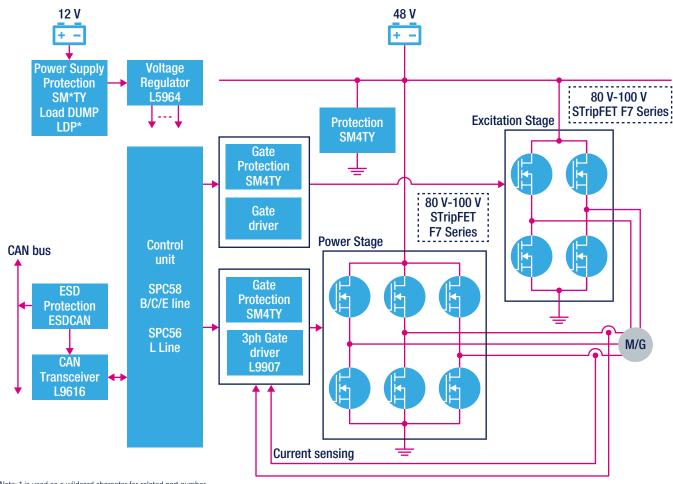
A Start-Stop system automatically shuts down and restarts the internal combustion engine to reduce the amount of idle time, thereby improving fuel economy and reducing CO2 emissions. This is especially useful in urban traffic environments where vehicles can spend significant amounts of time in traffic.

This requires power electronics that can handle high current during cranking and ensure reliability during engine cycles operating on/off at high temperatures.

ST's solutions include silicon power MOSFETs, protections, gate drivers and microcontrollers, in accordance to AEC-Q100 and AEC-Q101 standards.



Start-Stop system



Note: * is used as a wildcard character for related part number

FIND OUT MORE



On-Board Charger (OBC)

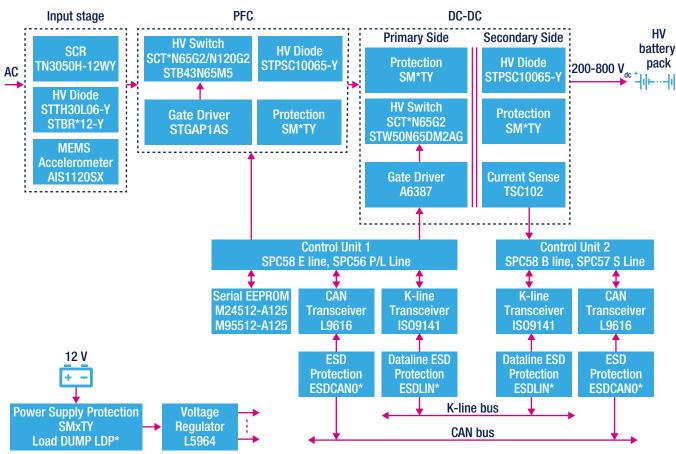
At the heart of any electric (EV) or plug-in hybrid (HEV) vehicle lies the high-voltage (200 to 800 Vdc) battery and its associated charging system. The on-board charger (OBC) provides the means to recharge the battery from the AC mains either at home or from outlets found in private or public charging stations.

From a 3.6 kW single-phase to a 22 kW three-phase high-power converter, today's OBCs must have the highest possible efficiency and reliability to ensure rapid charging times as well as meet the limited space and weight requirements.

ST has a wide offer of discrete semiconductors including AEC-Q101qualified silicon and silicon-carbide (SiC) MOSFETs and diodes as well as IGBTs. These are complemented by AEC-Q100 qualified galvanically isolated IGBT and MOSFET gate drivers and SPC5 32-bit automotive microcontrollers for implementing these challenging converters.



OBC



Note: $\ensuremath{^\star}$ is used as a wildcard character for related part number

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DC Fast Charging Station

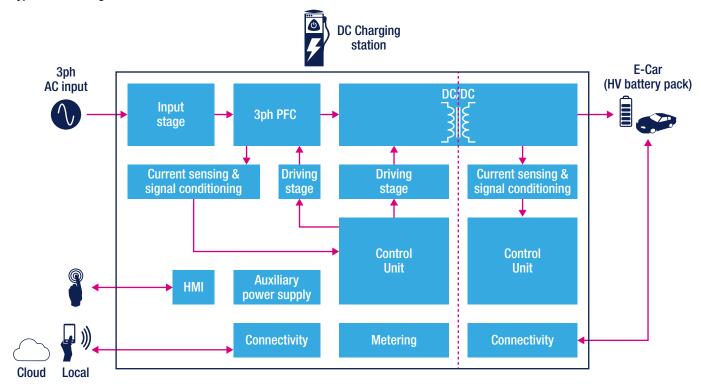
The number of full electric vehicles (EVs) is rapidly growing and, as a result, the charging infrastructure is also expanding, including DC fast charging stations, which have the attractive capability of providing the vehicle with a 100 km driving range in just 10-12 minutes.

While architectures based on renewable sources and battery storage technologies — to take charging stations off-grid - are emerging, mainstream solutions are fed from the grid and a converter — in the range of 120 kW or more - has a 3-phase input Power Factor Correction (PFC) stage and an isolated DC-DC converter. DC Charging stations also provide secure connectivity and authentication with the vehicle.

We can provide a range of power discretes including silicon-carbide (SiC) and silicon power MOSFETs and diodes, isolated gate drivers as well as high-performance STM32 microcontrollers to help develop high-efficiency, high-power density DC charging stations.



Typical Block Diagram





ST'S PRODUCT OFFERING FOR DC FAST CHARGING STATION

			Input	3ph			un	trol its	Driving	Current sensing & signal	Aux	НМІ	Metering	Connectivity	
			stage	PFC	1^ side	2^ side	1^ side	2^ side	stage	conditioning	SMPS		Motoring	1^ side	2^ side
	SiC series - 600/6	50 V		•		•									
	SiC series - 1200	V		•		•									
Doublifiana	Ultrafast RQ series	s - 600 V		•	•	•									
Rectifiers	Ultrafast R series	- 600 V		•	•						•				
	STBR series - 120	0 V	•	•											
	Schottky series - 40/45/60/100 V										•				
	TN series - 1200 \	I	•												
	TYN series - 1200	V	•												
Thyristors	TM8050H series -	800 V	•												
	TN3050H, TN5050)H series -1200 V	•												
TVS protections	SM4TY, SM6TY, SM	M15TY, SM30TY		•	•	•					•				
	SiC series - 650/1	200 V		•	•										
	M5 series - 650 V			•											
	M6 series - 600/6	50 V		•	•										
Power MOSFETs	DM6 series - 600/	650 V			•										
	DM2 series - 600/	650 V			•										
	K5 series - 1200 V	<i>I</i>		•							•				
	H series - 1200 V			•											
	HB series - 650 V			•	•										
IGBTs	HB2 series - 650 V			•	•										
	V series - 600V			•	•										
ACEPACK Power Modules	Customized modules			•	•										
	STM32F334, STM32G4, STM32F3			•	•		•								
MCUs (32bit)	STM32F0, STM32F1, STM32G0					•		•							
	L6491								•						
Gate drivers	STGAP1AS								•						
Memories (EEPROM)	M24**, M95**						•								
Current sense amplifiers	TSC102			•						•					
HV converters	VIPer06, VIPer16, \	/IPer26, VIPer26K									•				
Offline controllers	L6566BH, STCH02	2, STCH03									•				
Voltage regulators	L5963, L5964 L798*, L698*										•				
CAN transceivers	L9616														•
CAN ESD protections	ESDCAN Series								•				•		•
Power line	ST2100													•	•
transceivers	ST7540, ST7580,	ST8500												•	
Bluetooth	ICs	BlueNRG-MS, BlueNRG-1, BlueNRG-2												•	
Low Energy Transceiver	Modules	SPBTLE-1S, SPBTLE-RF, SPBTLE-RF0												•	
NFC/RFID	Dynamic tags	M24SR, ST25DV-I2C												•	•
	Readers	ST25R												•	•
Metering ICs	STPM32, STPM33	, STPM34											•		
LED arrray drivers	LED1642, STP08, LED8102S	STP16, LED77*,										•			

Note: * is used as a wildcard character for related part number

INDUSTRIAL POWER & TOOLS

Industrial Welding

Arc welding is an assembling process that joins metal parts by causing their fusion through high-current flowing through the electrode and the base material. The current, either DC or AC, is generated by a specifically designed high-frequency inverter switched mode power supply (SMPS) usually based on half-bridge, full-bridge, and two-transistor forward topologies.

The main requirements in an SMPS for welding are high efficiency and reliability as well as power density to enable lighter and more compact designs.

We have a range of power MOSFETS and diodes – both Si and SiC based for higher efficiency – and IGBTs as well as galvanically isolated gate drivers and high-performance 32-bit STM32 microcontrollers to enable compact designs with higher efficiency.

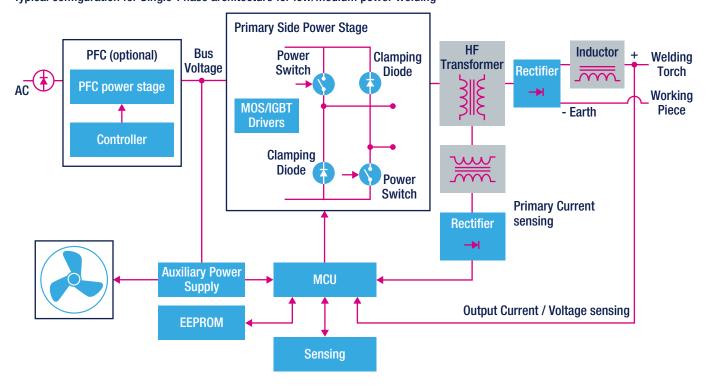


ST'S PRODUCT OFFERING FOR INDUSTRIAL WELDING

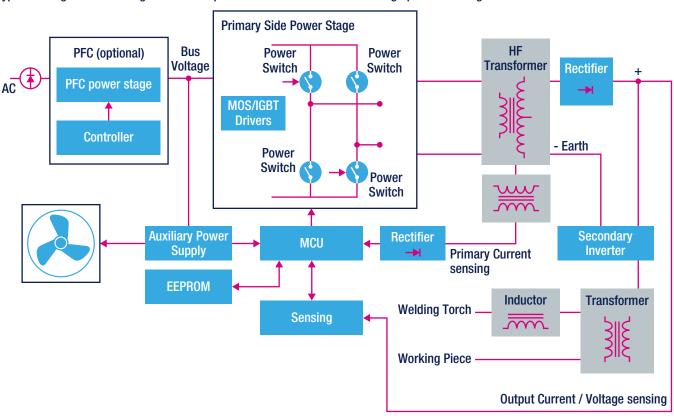
	MCUs & Digital Controllers	MOSFET/IGBT Gate Drivers	IGBTs	Power MOSFETs	Diodes
PFC	MCUs STM32F0 STM32G0 STM32F301 STM32F334 STM32G4 Digital Controllers STNRGPF01, STNRGPF12	Single LS Gate Drivers PM88*1, TD35* Multiple LS Gate Drivers PM8834 Isolated Gate Drivers STGAP* HV HB Gate Drivers L649*	600 V V series STG*V60F 650 V HB series STG*H65FB 650 V HB2 series STG*HP65FB2 1200 V H series STG*H120F2	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 650V MDmesh M5 ST*65M5 650 V-1200 V SiC MOSFETS SCT*N65G2, SCT*N120	600 V Ultrafast STTH*W06, STTH*R06, STTH*T06 1200 V Ultrafast STTH*S12 SiC Diodes STPSC*065, STPSC*12
DC-DC TTF			600 V V series STG*V60DF 650 V HB series	650 V MDmesh M5 ST*65M5 600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2	600 V Ultrafast STTH*R06, STTH*06 1000-1200 V Ultrafast STTH*10, STTH*12
DC-DC PS-FB	STM32F334 STM32G4 STM32F301 STM32F1 STM32F3	Isolated Gate Drivers STGAP* HV HB Gate Drivers L649*	STG*H65DFB 650 V HB2 series STG*H65DFB2 1200 V H series STG*H120DF2	600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V MDmesh DM6 ST*60DM6 800 V to 1200 V MDmesh K5 ST*80K5, ST*9*K5, ST*105K5, ST*120K5 650 V-1200 V SiC MOSFETs SCT*N65G2, SCT*N120	
Secondary Inverter			600 V V series STG*V60DF 650 V HB series STG*H65DFB 650 V HB2 series STG*H65DFB2	600 V-650 V MDmesh M2 ST*60M2, ST*65M2, ST*60M2-EP 600 V-650 V MDmesh DM2 ST*60DM2, ST*65DM2 600 V-650 V MDmesh M6 ST*60M6, ST*65M6 600 V MDmesh DM6 ST*60DM6	200 V to 400 V Ultrafast STTH*W02, STTH*W03, STTH*W04, STTH240F0 Power Schottky High Temperature STTH*10, STTH*12

Note: * is used as a wildcard character for related part number

Typical configuration for Single-Phase architecture for low/medium power welding



Typical configuration for Single and Three-phase architectures for medium/high power welding



Uninterruptable Power Supplies (UPS)

Uninterruptable Power Supplies (UPS) ensure continuity of supply by converting the DC voltage from a battery or battery bank to an AC voltage with the requested amplitude and frequency in case of power outages.

Depending on application requirements, an UPS can be built with a simple off-line configuration or with a double conversion online method for high-end, medium- or high-power UPSs. This also improves the quality of the power supplied to sensitive loads including computers, servers,



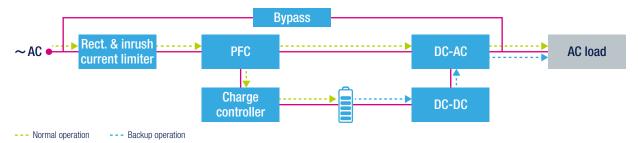
smart industry machines, instrumentation and telecommunication equipment. We offer high-performance discrete devices including high- and low-voltage power MOSFETs, IGBTs, thyristors and silicon-carbide (SiC) diodes and power MOSFETs as well as galvanically-isolated and high-voltage gate drivers, PFC controllers and high-performance STM32 microcontrollers to enable high-efficiency, high-reliability UPS designs.

ST'S PRODUCT OFFERING FOR UNINTERRUPTABLE POWER SUPPLIES (UPS)

		SCRs	& TRIACs	Diodes					SCRs & TRIACs
Rect. & inrush current limiter High Temp. SCR TN*015H-6, TN*050H-8, TN*050H-12W High Temp. Triacs T1635T		50H-8, TN*050H-12W emp. Triacs	Bridge Rectifier Diodes STBR*12			ass	Standard SCR TYN6*, TYN8*, TYN10*, TYN12* High Temp. SCR TN5050H-12WY Standard and Snubberless Triacs T2550-12, TPDV*		
	MCUs & D	Digital Controllers	Power MOSFETs	IGBTs	Diodes		Opamp V/I		
		MCUs STM32F0, STM32G0,			600 V Ultraf	last	Precision Op Amps (<50 MHz) TS*, TSV*, LMV*		
		301, STM32F334,	600 V-650 V MDmesh M	16 650 V HB series	STTH*R0	- V	MOSFET and IGBT	Gate Drivers	
PFC Block	,	STM32G4	ST*60M6, ST*65M6	STG*HP65FB	STTH*T06		Multiple LS Ga	te Drivers	
I I O DIOCK		al Cantuallana	650 V MDmesh M5	650 V HB2 series	SiC Diode		. PM883	34	
	Digital Controllers STNRG, STNRGPF01,		ST*65M5	STG*HP65FB2	STPSC*06	-	Single LS Gate Drivers		
	STNRG, STNRGPF112		SIC MOSFET	1200 V H series	STPSC*1		PM88*1		
	ŭ		SCT*N65G2	STG*H120F2				-	
		MCUs	Power MOSFETs	-	Diodes	N	MOSFET and IGB1	Gate Drivers	Protections
Charge Controller			600 V-650 V MDmesh N ST*60M2, ST*65M2 600 V-650 V MDmesh N ST*60M6, ST*65M6 600 V-650 V MDmesh DI ST*60DM2, ST*65DM2	16 M2			HV HB Gate L649 Isolated Gate STGAI	* e Drivers	TVS for MOSFET Protection SMA4F, SMB15F series
			600 V MDmesh DM6 ST*60DM6		600 V Ultraf STTH*06				
	S ⁻	TM32F334	Power MOSFETs	IGBTs	1200 V	Ν	MOSFET and IGB1	Gate Drivers	Post Regulation
		STM32G4 STM32F4 STM32F7		600 V V series STG*V60DF 650 V HB series	Ultrafast STTH*12 SiC Diode	2	Multiple LS Ga PM883		DC-DC Converters
DC-AC Stage			SiC MOSFET SCT*N65G2	STG*H65DFB 650 V HB2 series	STPSC*06 STPSC*1		Single LS Gat PM88		L698*, ST1S14, L7985, L7986, L7987*
				STG*H65DFB2			HV HB Gate	Drivers	Low Dropout (LDO) Linear Regulators
				STG*H120DF2			L649		LDF, LDFM, LDK220,
DC-DC Stage			60 V-100 V STripFET F7 ST*N6F7, ST*N8F7, ST*N10F7	7			Isolated Gate STGAI		LDK320, LDK715, LDL212

Note: * is used as a wildcard character for related part number

Example of high-end configuration (double-conversion system solution)



MAJOR HOME APPLIANCES

Refrigeration, washing, drying and miscellaneous equipment

The white goods market requires low-cost and high-energy-efficiency solutions. The refrigeration, washing, drying and the miscellaneous (Air conditioner, water heater) equipment are some of the major home applications that ST, thanks to the its wide product portfolio, is able to satisfy with suitable and dedicated power products and high-performing STM32 microcontrollers combined with complementary gate drivers (L638* and L649*). Using SiC diodes (STPSC*), new high-voltage MDmesh MOSFETs or suitable field-stop trench-gate IGBTs, high-efficiency PFC is guaranteed. To reduce the 3-phase inverter design effort, ST offers the SLLIMMTM family (small low-loss intelligent molded module) of highly-integrated, high-efficiency intelligent power modules

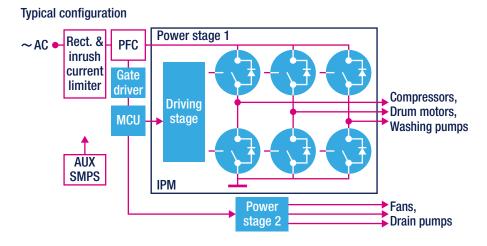


(IPM) integrating the power stage (both on IGBT and MOSFET discretes), driving network and protections. Another approach for designing a 3-phase inverter is based on the use of six discrete IGBTs/MOSFETs with the new 3-phase gate drivers STDRIVE601. High reliability against the inrush current is ensured by new SCRs in the front-end stage. STPW programmable electronic power breaker family provides a convenient, integrated solution for quickly and safely disconnecting a faulty load from a 12 V bus.

ST'S PRODUCT OFFERING FOR REFRIGERATION, WASHING, DRYING AND MISCELLANEOUS EQUIPMENT

		SCRs & 1	TRIACs	Diodes			LED Di	ivers		HV Converters
High Temp. SCR		Bridge Rectifier Dioc STBR*12	Bridge Rectifier Diodes STBR*12		LED Array Drivers STP04/08/16/24 LED12/16/24*		AUX SMPS	VIPerPlus		
	MCUs	& Digital Controllers	IGBTs	Diodes		Opamp V/I Sei	nsing	Pow	er MOSFETs	Power Breakers
PFC Block	STM: STM	MCUs M32F0, STM32G0, 32F103, STM32F301, M32F334, STM32G4, STM32F4 Digital Controllers TNRG, STNRGPF01, STNRGPF12	600 V V series STG*V60F 650 V HB series STG*HP65FB 650 V HB2 series STG*HP65FB2	STTH*AC06 STTH*R06 STPSC*065 DLF	MOS	cision Op Amps (TS*, TSV*, LN FET and IGBT G Wultiple LS Gate PM8834 Single LS Gate I PM88*1	AV* ate Drivers Drivers	ST*60 600 V-65 ST*60 650 V	50 V MDmesh M2 M2, ST*65M2 50 V MDmesh M6 M6, ST*65M6 V MDmesh M5 ST*65M5 C MOSFET CT*N65G2	STPW05, STPW12
		MCUs	IGBTs	IPM	MOS	FET and IGBT G	ate Drivers	Pow	er MOSFETs	Post Regulation
3Ph Inverter Compresso Drum Moto Fan, Pumps	, STM:	M32F0, STM32G0, 32F103, STM32F301, M32F334, STM32G4, STM32F4	600 V H series STG*H60DF 650 V M series STG*M65DF2	IPM for compressor and drum motor STGIPQ*60T-H STIPQ*M60T-H STGIF*CH60(T)S-L(E) STGIB*CH60(T)S-L(E) STGIB*M60(T)S-L(E) STIB*60DM2T-L IPM for fan and pumps STIPNS*M50T-H STGIPNS*H60T-H STGIPQ*M60 STGIPQ*60T-H	:	3-Phase HV Gate STDRIVE60 HV HB Gate Dr L638*, L649 Isolated Gate D STGAP*	ivers 9*	ST*60D 600 V S	0 V MDmesh DM2 M2, ST*65DM2 MDmesh DM6 T*60DM6 C MOSFET CT*N65G2	DC-DC Converters L698*, ST1S14, L7985, L7986, ST1S4*, ST1S50 Low Dropout (LD0) Linear Regulators LDF, LDFM, LDK220, LDK320, LDK715, LDL212

Note: * is used as a wildcard character for related part number





Induction Cooking

Induction cooking ranges must be efficient, safe and provide friendly user interfaces. Resonant-switching topologies are typically used for the power converter in these appliances, as they also help achieve lower levels of electro-magnetic interferences (EMI).

We have specifically developed trench-gate field-stop IGBTs and diodes that, together with a selection of high-voltage gate drivers and high-performance STM32 microcontrollers, are ideal for high-efficiency converters. ST also offers environmental sensors and the LED and LCD display drivers, touchscreen controllers and proximity and sensors required for touch or touchless user interfaces.

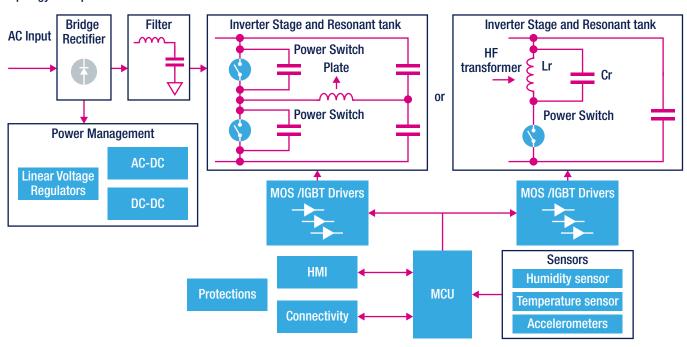


ST'S PRODUCT OFFERING FOR INDUCTION COOKING

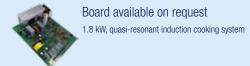
	MCUs	IGBTs		MOSFET and IC	BT Gate Drivers		Sensors		
Single-switch quasi-resonant (voltage resonance)	STM8* STM32F100	1250 V IH series STG*IH125DF	6	Multiple LS Gate Drivers PM8834 Single LS Gate Drivers PM88*1			Enviromental Sensors Humidity - HTS221 Temperature - STLM20		
	MCUs	IGBTs	IGBTs		BT Gate Drivers	Temperature - STTS751			
HB series resonant (current resonance)	STM32F0, STM32G0 STM32F100	600 V HB series STG*H60DLFB 650 V IH series STG*IH65DF		HV HB Gate Drivers L649* Isolated Gate Drivers STGAP*		Motion Sensors Accelerometer IIS3DHHC			
	MCUs	LED Drivers		AC-DC	DC-DC		LD0		
User interface (front panel)	STM8, STM32F0, STM32G0, STM32F4*9, STM32F7*	LED Array Drivers STP04/08/16/24, LED1642GW, LED8102S, LED12/16/24*	Power Managemo	ent VIPerPlus	L698*, ST1S14, L7986, L798	,	LDF, LDFM, LDK220, LDK320, LDK715, LDL212		

Note: * is used as a wildcard character for related part number

Topology example



MAIN EVALUATION BOARD





Software tools

eDesignSuite

eDesignSuite is an easy-to-use, comprehensive software suite ready to help customers define their needs by transforming their application requirements into satisfactory solutions based on the wide range of ST products. The suite includes a smart simulator and system design engine able to suggest products and topologies for various types of applications (power supply, photovoltaic, battery charger, LED lighting, signal conditioning and RF design); smart selectors to help select the types of products (e.g. diodes) best suited to your application; and configurators to reduce implementation time and efforts for setting product parameters for the specific application (e.g. STLUX & STNRG SMEDs for lighting and power, Workbench for motor control). To discover and test all the features of eDesignSuite, you can visit (after the online registration) https://mv.st.com/analogsimulator/

eDesignSuite

The smart way to design your application











SMART SIMULATOR AND SYSTEM DESIGN ENGINE

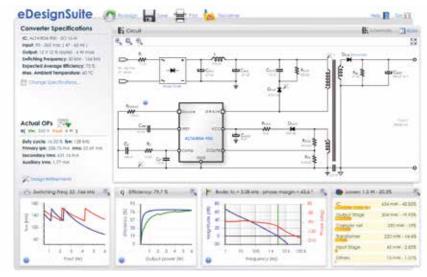
Power conversion and LED lighting

- Automatic proposal for complete solution or fully customizable design
- Fully annotated and interactive schematics
- Complete and interactive bill of materials
- Set of analysis diagrams (main current and voltage simulations, efficiency curves, Bode stability and power-loss data)
- Fully interactive transformer design
- New iPFC design based on STNRGPF01 and STNRGPF12 digital controllers including c code generation

SMART SELECTOR

Diodes

- Part numbers proposed based on application electrical specifications
- I-V curves comparison among several part numbers
- Power losses calculated based on voltage/current target application waveforms



Smart simulator and system design engine view

CONFIGURATORS

STLUX & STNRG SMEDs configurator

- SMED configurator schemes
- Input configuration
- Clock, comparators and ADC settings
- FSM (finite state machine) configuration
- C code generation
- Load register setting on board in a click



AC-DC CONVERSION ICs

High-voltage converters

ST's **high-voltage AC-DC converters** combine an advanced pulse width modulation (PWM) controller with a high-voltage power MOSFET in a single package. This makes them ideally suited for offline switch mode power supplies (SMPS) with output power spanning from a few to a few tens of watts.

The **VIPerPlus series** (VIPer0P, VIPer122 and VIPer*1, VIPer*5, VIPer*6, VIPer*7, VIPer*8 families) features an 800 V avalanche-rugged power MOSFET and leading-edge PWM controller and consumes less than 4 mW for VIPer0P, 10 mW for VIPer*1 and 30 mW in standby for the others. It also comes with the largest choice of protection schemes and supports different topologies.

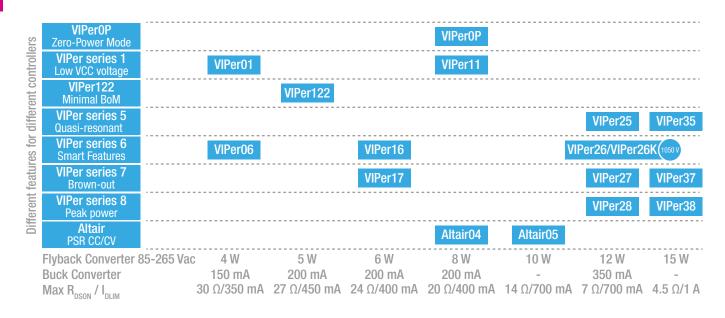
The VIPer26K belongs to VIPer*6 family and integrates a 1050 V avalanche-rugged power MOSFET, suitable for cost effective 1-phase/3-phases smart meters, industrial systems and lighting power supplies.

The Altair series has a built-in 800/900 V avalanche-rugged power MOSFET and a PWM controller specifically designed to work in constant-current/constant-voltage primary-side regulation (PSR-CC/CV). It means opto-less implementation, thus significantly reducing component count.



- Increased robustness using up to 1050 V AR MOSFET
- Extremely low consumption
- · Better integration and minimal BoM
- Flexible and easy to use

- Flyback topology supported
 - · Regulation with optocoupler using all ICs
 - PSR-CV using VIPer0P, VIPer122, VIPer*1 and VIPer*6
 - PSR-CV/CC tight tolerance using Altair
- Buck & buck-boost topologies supported by VIPerOP, VIPer122, VIPer*1 and VIPer*6





www.st.com/viperplus www.st.com/ac-dc-converters www.st.com/high-voltage-ac-dc-converters

PFC controllers

ST power factor correction (PFC) controllers operate in transition mode (TM, suitable for P ≤250 W) and continuous current mode (CCM, suitable for P >250 W), and are suitable for a wide-range-mains operation.

These devices embed advanced protection features, which make SMPS more robust and compact, requiring fewer external components. These features include output overvoltage, brown-out, feedback disconnection and boost inductor saturation protection. The high-voltage start-up capability, present in the L6564H and L6563H, helps improve the SMPS standby efficiency in systems that do not include an auxiliary power supply.

TM PFC controllers



CCM PFC controllers



MAIN APPLICATIONS





Adapters and TVs L6562A*, L6563*, L6564*

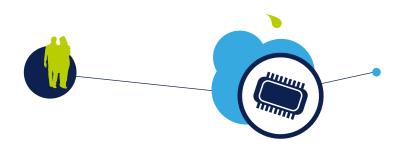








Commercial and street lighting L6562A*, L6563*, L6564*, L4981*, L4984D **Desktop PCs and Server** L4981*, L4984D



PWM and resonant controllers

ST's portfolio of advanced controllers includes a variety of **primary controllers** intended to fit high-performance applications. Very high efficiency is achieved with single-ended topologies at a fixed switching frequency or with quasi-resonant operation; the new STCHO3 offline constant-current primary-side regulation controller (PSR-CC) guarantees very low power consumption at no load condition. For high-power, high-current applications, ST offers controllers for half-bridge resonant and asymmetrical half-bridge topologies. The new STCMB1 and STNRG011 combo controllers including high-voltage start-up, Xcap discharge circuit, PFC and resonant driving stages, guarantee high performance and high integration with a smaller pinout.

Flyback controllers

STCH02/STCH03

- Offline quasi-resonant controller in SO-8 package
- Constant-current primary-side regulation mode (PSR-CC) or constant-voltage regulation with optocoupler
- Advanced burst mode operation (< 10 mW consumption @ no load)
- UVP, autorestart/latched OVP and internal OTP (only for STCH03)
- 650 V HV start up

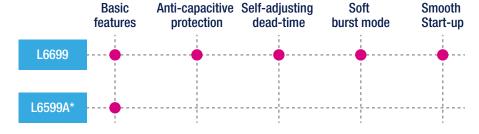
L6566*

- Offline fixed-frequency or quasi-resonant controllers
- Suited for SMPS with PFC front-end (A version)
- Suited for SMPS with 3-phase mains (BH version)
- 700 V start up (A/B version), 840 V start up (BH version)

L6565

- Offline quasi-resonant controller
- · Constant power vs mains change
- Ultra-low start-up current

HB-LLC resonant controllers



Analog combo controller (PFC+LLC/LCC)

STCMB1

- 800 V start-up voltage
- Embedded X-cap discharge circuit
- Transition Mode (TM) PFC control method
- Self-adjusting dead-time and anticapacitive mode for LLC

Multi-mode digital combo controller (PFC+LLC/LCC)

STNRG011

- Onboard 800 V startup circuit, line sense and X-cap discharge compliant with IEC 62368-1, for reduced standby power
- Enhanced fixed on time multi-mode TM PFC controller
- Time-shift control of resonant half-bridge
- ROM memory for SW digital algorithms
- NVM memory for programmable key application parameters

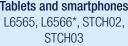
Asymmetrical half-bridge controller

L6591

- PFC interface
- Brown out
- 700 V start-up voltage

MAIN APPLICATIONS







Laptops L6565, L6566*, STCH02, STCH03, STCMB1, STNRG011



High-power adapters and TVs L6565, L6566*; L6599A*, L6699, STCMB1, STNRG011



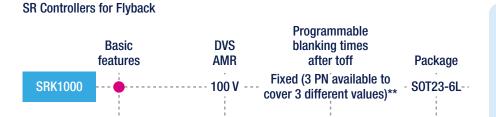
Desktop PCs, commercial and street lighting L6599A*, L6699, STCMB1, STNRG011

www.st.com/ac-dc-converters www.st.com/pwm-controllers www.st.com/resonant-controllers

Synchronous rectification controllers

Synchronous rectifiers are used to drive power MOSFETs that replace the rectification diodes in the secondary side of SMPS, thus providing high efficiency especially in low-output-voltage, high-current power supplies.

The product portfolio supports the most common flyback and LLC resonant topologies. The main benefits include high efficiency, space saving, cost reduction and high reliability.

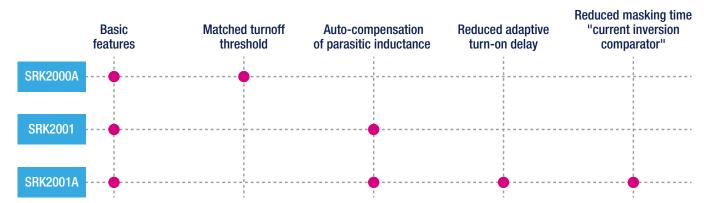


SRK1001 -- • 185 V ----- 185 V : **Three options available: SRK1000 (0.5 μs), SRK1000A (2 μs), SRK1000B (3 μs)

SYNCHRONOUS RECTIFICATION BENEFITS

- Improved efficiency
- Better thermal performance
- High power density
- Increased reliability

SR controllers for LLC resonant



MAIN APPLICATIONS High-nower adapters and TVs

High-power adapters and TVs SRK1000, SRK1001



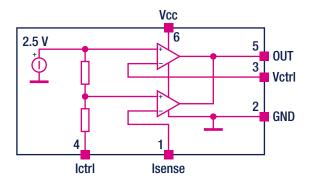
S08 ---



Voltage and current controllers

ST offers a wide range of highly-integrated **voltage controllers** for constant-voltage (CV), constant-current (CC) SMPS applications, such as adapters, battery chargers and LED pilot lamps. They enable a more robust design, safer SMPS, very low power dissipation and low stress for secondary-side components.

SEA05 internal block diagram



CC/CV controllers for chargers, adapters and others

SEA01

- Advanced CC/CV controller with online digital trimming
- 0.1% voltage reference precision up to 36 $V_{\rm cc}$
- 200 µA low quiescent current

SEA05

SEA05L

- Advanced CC/CV controller (SEA05)
- Advanced CC/CV controller with efficient LED pilot lamp driver (SEA05L)
- 0.5% voltage reference precision up to 36 $\rm V_{cc}$
- Low quiescent current: 200 μA (SEA05), 250 μA (SEA05L)
- Current sense threshold 50 mV (SEA05)
- 4% current loop precision (SEA05L)

TSM10*

- Compact solution
- Easy compensation
- 0.5 and 1% voltage reference precision

MAIN APPLICATIONS

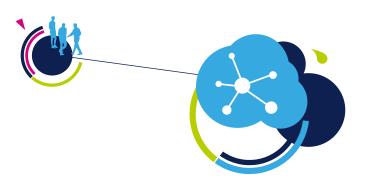








and street lighting



Signal conditioning

Signal conditioning devices include **Operational Amplifiers** and **Current Sensing amplifiers**. These devices enable accurate and fast current measurement in power supplies. **Comparators** are also very powerful allies of the power supply designer to implement protection features such as over-temperature, over-current, and over/under voltage.

Operational Amplifiers

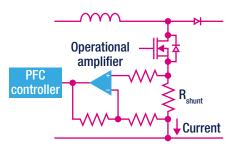
TSZ181, TSZ182

- 5 V zero-drift amplifier
- Input offset voltage 15 μV max
- Gain bandwidth 3 MHz

TSB712, TSB7192

- 36 V amplifier
- Input offset voltage 300 µV max
- Gain bandwidth 6 MHz (unity gain stable) or 22 MHz

Typical application schematic for low-side current measurement in a PFC



Current Sensing Amplifiers

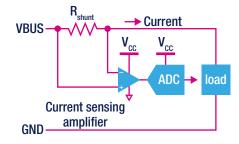
TSC103

- Operating voltage 2.9 to 70 V
- Surviving voltage on shunt -16 to 75 V
- Amplification gain x50 x100
- Package TSSOP8, SO8

TSC101

- Operating voltage 2.8 to 30 V
- Surviving voltage on shunt -0.3 to 60 V
- Amplification gain x20 x50 x100
- Package S0T23-5

Typical application schematic for high-side current measurement



Comparators

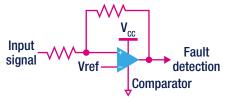
TS3021, TS3022

- Propagation delay: 38 ns
- Low current consumption: 73 μA
- Rail-to-rail inputs
- Push-pull outputs
- Supply operation from 1.8 to 5 V

TS3011

- Propagation delay: 8 ns
- Low current consumption: 470 μA
- Rail-to-rail inputs
- Push-pull outputs
- Supply operation from 2.2 to 5 V

Typical application schematic for fault detection using a non-inverting comparator, with hysteresis



MAIN APPLICATIONS









UPS



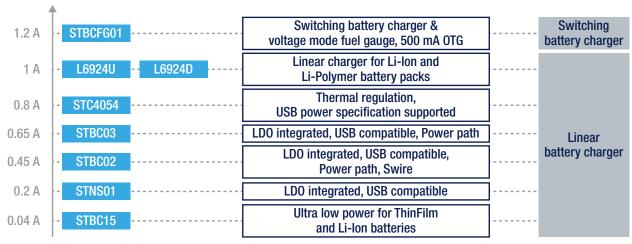


BATTERY MANAGEMENT ICs

Battery chargers and battery monitoring ICs

ST's **battery chargers** are specifically designed for the portable and mobile markets, and add value to new designs by minimizing power consumption and reducing the space on the PCB. These products offer charge currents from as little as 40 mA up to 1.2 A and can be used for any rechargeable lithium-ion and Li-Polymer battery. Using very simple topologies, some of these devices also feature a power-path function offering instant-on operation and thermal regulation according to the JEITA international standard.

Battery chargers



STBC02/ STBC03

- Embed a linear battery charger, a 150 mA LDO, 2 SPDT load switches and a protection circuit module
- STBC02 embeds a smart reset/watchdog and a single wire interface for IC control
- Use a CC/CV algorithm with programmable (only STBC02) fast charge, precharge and termination current

STBC15

- · Microbatteries charging and monitoring circuit
- Charging current up to 40 mA (set by dedicated pin)
- 150 nA quiescent current

ST's **battery fuel gauge ICs** can be located in the battery pack or in the handheld device and integrate functions to monitor the battery voltage, current and temperature. Using a built-in Coulomb counter, these fuel gauge ICs calculate battery charge and store the data in 16-bit register resolution for retrieval by the system controller. Access is via an industry-standard I²C interface, enabling the controller to create an accurate graphical representation of the remaining battery-operating time.

STC3115

- OptimGauge™ algoritm for STC3115
- OptimGauge+™ algorithm for SCT3117
- STC3117
- Coulomb counter and voltage gas gauge operations
- Programmable low battery alarm
- Internal temperature sensor

FUEL GAUGE ICS MAIN BENEFITS

- 3 % accuracy of battery state of charge no need for shunt resistor
- Accurate estimation of battery state of charge at power-up
- Reliable battery swap detection
- SoH and impedance tracking with OptimGauge+ algorithm (ST IP)
- Charger enable and system reset control for accurate OCV reading

MAIN APPLICATIONS





USB L6924U, STC4054, STBCFG01



Fitness STNS01, STBC02, sSTBC03





Smartphones STBCFG01, STC3115, SCT3117

Wireless charging ICs

ST fully covers wireless charging applications with **dedicated ICs for both transmitter and receiver**. The STWBC and STWBC-EP, compatible with Qi standard, and the STWBC-WA, dedicated to wearable applications, make-up ST's wireless power transmitters (Tx) family. The receiver family (Rx) consists of the STWLC33 dedicated to Qi compliant consumer applications.

Vbus monitor

5 or 3.3 V input

2x LED

ADC

GPIOs

UART

I²C

Customizable

Wireless power transmitters



STWBC

- Supports applications up to 5 W
- Qi A11 certified

STWBC-WA

- Supports applications up to 2.5 W
- Wireless power transmitter dedicated to wearables

STWBC-FP

- Supports application up to 15 W
- Qi extended power certified

STWBC-MC

- Support multi-coil applications up to 15 W
- Qi extended power certified

Common features

Digital feedback with foreign object detection (FOD)



• GUI for configuration and run-time analysis

• Firmware customization via API

Digital bridge controller

Temperature

protection

Overcurrent

protection

Signal and protocol

demodulator

FOD

Active object detector

0.01.101.001111

Wireless power receivers

STWLC33

STWLC33

- Supports up to 15 W output power in RX mode and 5 W in TX mode
- Qi compliant
- Outstanding total system efficiency
- Precise voltage and current measurements for FOD function

MAIN APPLICATIONS



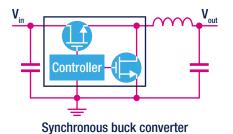


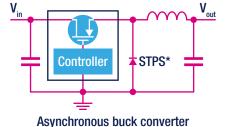


DC-DC SWITCHING CONVERSION ICs

DC-DC converters

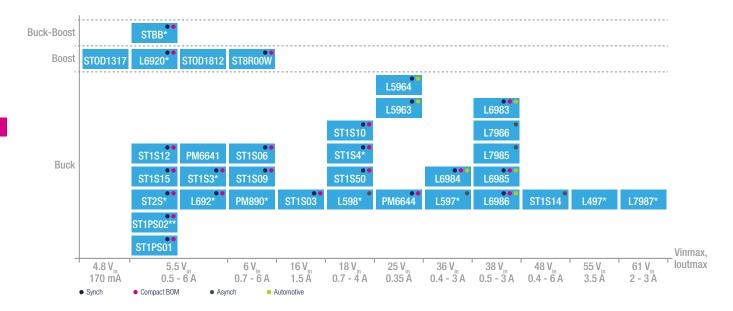
ST offers a wide portfolio of monolithic **DC-DC switching converters** (i.e. controller and MOSFET in the same package). This broad portfolio of ICs is composed of highly-specialized products to meet every market requirement. High reliability and robustness for industrial (factory automation, UPS, solar, home appliances, lighting, etc.) and other high-voltage applications. High efficiency at any load and a high level of performance for consumer (smartphones, digital cameras, portable fitness devices, LED TVs, set top boxes, Blue-ray players, computer & storage, etc) and server/telecom applications.

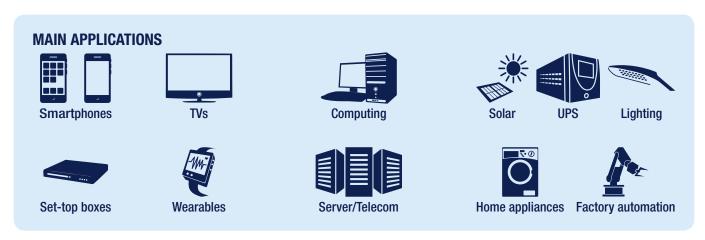




DC-DC CONVERTERS MAIN FEATURES

- Up to 61 V_{III}/3 A
- Synchronization capability
- Internal compensation
- Low consumption
- Adjustable fsw
- Internal soft start
- · Low quiescent current





DC-DC controllers

L673*

ST offers a wide portfolio of **DC-DC switching controllers** for server and telecom applications according to market requirements: single-phase controllers with embedded drivers, advanced single-phase controllers with embedded non-volatile memory (NVM), and our newest controllers with or without SPS (Smart Power Stage) compatibility as well as multiphase digital controllers for CPU & DDR memory power supplies.

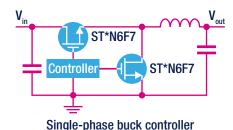
Single-phase Buck controllers

L672* Single- phase cost effective PWM controller

Single-phase PWM controller with embedded driver and light load efficiency optimization

PM6697 Analog single-phase controller with SVID with embedded gate driver

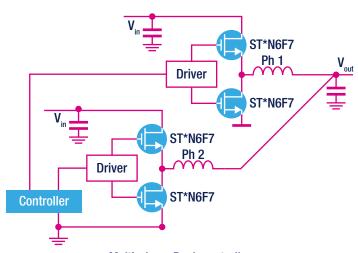
PM6680 Dual-output PWM controller up to 36Vin



Multi-phase Buck controllers

PM676* Fully digital buck controller with PMBus for CPU/DDR

PM677* Fully digital buck controller with PMBus for advanced CPU/DDR



Multi-phase Buck controller

MAIN APPLICATIONS









DIGITAL POWER CONTROLLERS AND MICROCONTROLLERS

Digital power controllers

ST's offers a number of advanced digital controllers, featuring innovative solutions to optimize converter efficiency in a wide range of load conditions (especially at light loads) and to have more flexibility. ST offers two main digital controller families tailored for specific applications: STLUX for lighting and STNRG for power conversion. In STLUX and STNRG families, the innovative SMED (state machine, event-driven) digital technology and the integrated microcontroller make STLUX and STNRG easily programmable and versatile. SMED is a hardware state machine triggered by internal or external events.

Digital controllers tailored for power conversion and lighting applications

STNRG*

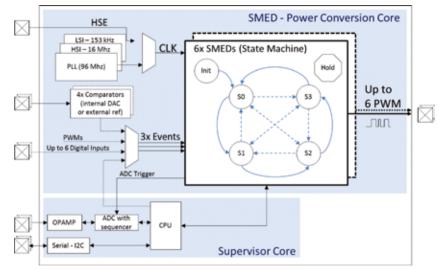
STLUX*

Common features

- Innovative digital control technique based on 6 programmable SMEDs with max PWM resolution of 1.3 ns
- · Customizable algorithm for higher conversion efficiency
- Internal 96 MHz PLL
- Operating temperature -40 to 105°C
- Serial, I2C and GPIO interfaces

STNRG*

- Digital controller tailored for power conversion
- Up to 4 comparators with external reference



STNRG* internal block diagram

STI UX*

- Digital controller tailored for lighting applications
- Suitable for primary-side regulation and multi-strings lighting applications
- DALI 2.0 for remote control and connectivity

Digital controller for interleaved CCM boost PFC

STNRGPF01

STNRGPF12

- · Digital controller fully configurable through GUI for fast and easy design, does not require writing any firmware
- Mixed signal architecture
- 3-channel interleaved boost PFC (STNRGPF01)
- · 2-channel interleaved boost PFC (STNRGPF12)
- Digital inrush current limiter (STNRGPF12)
- Ideal for wide power range above 500 W
- · Reduced EMI filter and inductor volume
- Reduced output capacitor RMS current
- Flexible working frequency up to 300 kHz to drive both MOSFETs and IGBTs
- Configurable phase shedding for wide load range high efficiency conversion
- Programmable fast overcurrent and thermal protection (STNRGPF12)
- On-chip UART/I²C digital interfaces for convenient connectivity
- Ideal for outdoor applications with -40 to +105 °C operating range

MAIN APPLICATIONS



Solar STNRG*



HEV charging stations STNRGPF01, STNRGPF12



UPS STNRG*



Factory automation STNRGPF01, STNRGPF12





Commercial, architectural and street lighting STLUX*

> www.st.com/stlux www.st.com/stnra

Microcontrollers for digital power

The **32-bit microcontrollers** most suitable for power management applications are the STM32F334 and the STM32G474 MCU from the mixed-signal **STM32F3 series** and **STM32G4 series**, the STM32H743 MCU from the high performance **STM32H7 series** and those of the entry-level **STM32G0 series**.

The STM32G0 series has a 32-bit ARM® Cortex®-M0+ core (with MPU) running at 64 MHz and is particularly well suited for cost-sensitive applications. STM32G0 MCUs combine real-time performance, low-power operation, and the advanced architecture and peripherals of the STM32 platform.

The STM32F3 series MCU combines a 32-bit ARM® Cortex®-M4 core (with FPU and DSP instructions) running at 72 MHz with a high-resolution timer and complex waveform builder plus event handler.

The STM32G4 series and his 32-bit ARM® Cortex®-M4+ core running at 170 MHz is in the continuity of STM32F3 series, keeping leadership in analogue leading to cost reduction at the application level and a simplification of the application design, he explores new segments and applications.

Finally, the STM32H7 series has a 32-bit ARM® Cortex®-M7 running at 480 Mhz with precision FPU, DSP and advanced MPU. These MCU specifically address digital power conversion applications such as digital switched-mode power supplies, lighting, welding, solar, wireless charging, motor control and way more.

STM32G0

- Cortex®-M0 core
- Very low power consumption
- Timer frequency up to 128 Mhz resolution (8ns)
- High-speed ADCs for precise and accurate control
- More RAM for Flash: up to 36 KB SRAM for 128 KB and 64 KB Flash memory

STM32F334

- Cortex®-M4 core
- High resolution timer V1 (217ps resolution) with waveform builder and event handler
- 12-bit ADCs up 2.5 Msps conversion time
- Built-in analog peripherals for signal conditioning and protection (25ns from fault input to PWM stop)

STM32G474

- Cortex®-M4+ core
- High resolution timer V2 (184ps resolution) with waveform builder and event handler
- Mathematical accelerator, digital smps and power factor correction
- High-speed ADCs for precise and accurate control (4Msps)
- Dual bank flash for live upgrade

STM32H743

- Cortex®-M7 core
- High performance up to 480 MHz
- High resolution timer V1 (2.1ns resolution) for real time control
- High-speed ADCs for precise and accurate control (3.6 Msps)

STM32G474 block diagram

Connectivity

4x SPI, 4x I²C, 6x UxART

1x USB 2.0 FS,

1x USB-C PD3.0 (+PHY)

3x CAN-FD

2x I²S half duplex, SAI

External interface

FSMC 8-/16-bit (TFT-LCD, SRAM, NOR, NAND) Quad SPI

Accelerators

ART Accelerator™
32-Kbyte CCM-SRAM

Math Accelerators

Cordic (trigo...)

Filtering

Arm® Cortex®-M4 Up to 170 MHz 213 DMIPS

Floating Point Unit

Memory Protection Unit

Embedded Trace Macrocell

16-channel DMA + MUX

Up to 2x 256-Kbyte Flash memory / ECC Dual Bank

96-Kbyte SRAM

Timers

5x 16-bit timers

2x 16-bit basic timers

3x 16-bit advanced motor control timers

2x 32-bit timers

1x 16-bit LP timer

1x HR timer (D-Power) 12-channel w/ 184ps (A. delay line)

Analog

5x 12-bit ADC w/ HW overspl

7x Comparators
7x DAC (3x buff + 4x non-buff)

t Brio (ex Buil 1 1x Hell Bu

6x op-amps (PGA)

1x temperature sensor

Internal voltage reference

Digital Power Supply and PFC Design Workshop with STM32 MCUs in collaboration with the company partner Biricha (from Q4 2019)







Solar





and street lighting







Commercial, architectural Server/Telecom

Factory automation

www.st.com/stm32

Automotive Microcontrollers for in-car digital power

SPC5 automotive microcontrollers family are suited for in-car digital power applications such as traction inverters, on-board chargers, bidirectional DC/DC as well as Battery Management Systems.

SPC58 E-line combines real-time behavior with ISO26262 ASIL-D safety.

The embedded hardware security module (HSM) ensures protection against cyber security attacks.

The Generic Time Module (GTM) completes the peripheral set by delivering a high-performance timer, synchronization units, embedded hardware DPLL and micro-cores.

SPC58 Chorus family provides a connected, secure and scalable platform delivering a wide range of communication interfaces and low-power capabilities to complete the in-car connectivity needs.

SPC5 E	SPC58 E Line
Core	Triple 3x e200z4d @ 180 MHz
eFlash Code	4 MB to 6 MB
Timers	GTM3
Safety	ASIL-D
Advanced Networking	8x CAN-FD FlexRay 2x Ethernet
Security	HSM medium
ADC	5x 12 bit (SAR) 3x 10 bit (SAR) 6x 16 bit (SigmaDelta)
High Temperature support (165 Tj)	Qualified

Package Options



eTQFP 64-176 (exposed pad)



QFN 48 (exposed pad)















Scalability

Up to: 3 cores, 200 HMz, 10 MB flash



Secure & Safety





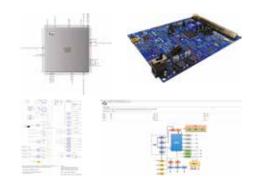


ST offers a complete ecosystem rich of partners, discovery tools, and the free to download SPC5-Studio IDE containing all peripherals drivers and graphical interface for configuration.













MAIN APPLICATIONS







Software over-the-air



Parking Services



Remote Assistance

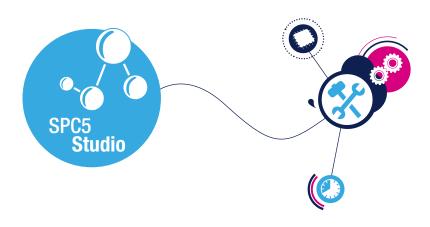


Maintenance free



Safety



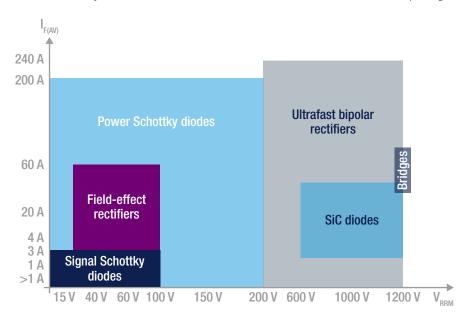


Silicon diodes

DIODES AND RECTIFIERS

ST offers **Schottky** and **ultrafast silicon rectifier solutions** for all market requirements. ST's latest developments include M series, based on Schottky technology, with improved avalanche rating and the integration of higher currents in low-profile PSMC (TO-277A) and PowerFLATTM packages. Our range of small-signal Schottky diodes with flip-chip and SOD-923 devices helps meet the most stringent space-saving requirements, especially for portable communication equipment.

For high-efficiency rectification or freewheeling functions, our new field-effect rectifier diodes, the FERD family, improve the power density capability of the converters. Power Schottky diodes are also available in thin SOD123Flat and an SOD128Flat packages.



Field-effect rectifiers (FERD)

FERD*

64

Low voltage diodes, for high efficiency and high power density applications

Power Schottky diodes

STPS*

Power Schottky diodes for low voltage general purpose applications

Ultrafast rectifiers

STTH*

Ultrafast high voltage diodes for general purpose application

MAIN APPLICATIONS



















Solar inverters, welding, HEVs, and UPS

Residential, commercial, architectural and street lighting













Home appliances



Consumer electronics

www.st.com/schottky www.st.com/ultrafast-rectifiers www.st.com/field-effect-rectifier-diodes

SiC diodes

ST's **silicon carbide diodes** range from 600 to 1200 V – as single and dual diodes – and feature unbeatable reverse recovery characteristics and improved VF. Available in a wide variety of packages, from D²PAK and the new PowerFlat 8x8 HV to TO-247 and the insulated TO-220AB/AC, they offer great flexibility to designers looking for efficiency, robustness and fast time-to-market.

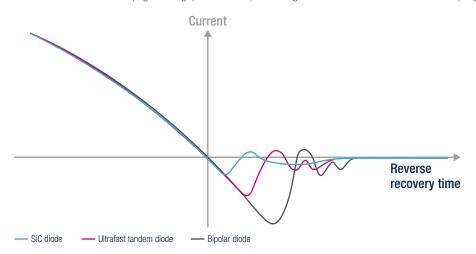
ST's SiC Schottky diodes show a significant power-loss reduction and are commonly used in hard-switching applications such as high-end-server and telecom power supplies, while also intended for solar inverters, motor drives and uninterruptible power supplies (UPS).ST's automotive-grade 650 and 1200 V SiC diodes – AEC-Q101-qualified and PPAP capable – feature the lowest forward voltage drop (VF) on the market, for optimal efficiency in electric vehicle (EV) applications.

Main characteristics:

- High efficiency of the power converter (thanks to low forward conduction and switching losses)
- High power integration with dual diodes for reduced PCB form factor
- · Significant reduction of power converter size and cost
- Low EMC impact, for simplified certification and reduced time-to-market
- Natural high robustness ensuring very high reliability

Our range of 1200 V silicon-carbide (SiC) JBS (Junction Barrier Schottky) diodes meet designers' needs for superior efficiency, low weight, small size, and improved thermal characteristics for performance-oriented applications.

Offering the best-in-class forward voltage (lowest VF) and state-of-the-art robustness, our 1200 V SiC diodes provide extra freedom to achieve high efficiency and reliability with lower current rating and therefore lower cost, while reducing operating temperature and extending application lifetime. The 1200 V SiC diode family covers current ratings from 2 to 40 A, including automotive-qualified devices, in surface-mount PowerFlat 8x8 HV, D2PAK HV and DPAK HV (high-voltage) and D2PAK, or through-hole TO-220AC and TO-247LL (long-lead) packages.



SIC DIODES BENEFITS

- High efficiency adding value to the power converter
- Reduced size and cost of the power converter
- Low EMC impact, simplifying certification and speeding time to market
- High robustness ensuring high reliability of the power converter
- Gain on PCB and mounting cost with the dual diodes

650 V SiC diodes in insulated TO-220 packages: the solution to speed production

STPSC*065

STPSC*13

- 650 V (STPSC*065)
- 2 x 650 V (STPSC*13) dual in series diodes
- Best trade-off between efficiency and robustness thanks to the high Ifsm
- · Ideal for applications with high current surge

MAIN APPLICATIONS









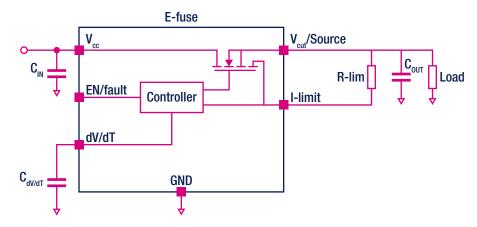
www.st.com/sic-diodes

HOT-SWAP POWER MANAGEMENT

E-fuses

E-fuses are electronic fuses that can replace larger conventional fuses or other protection, reducing ownership costs in production and in the field.

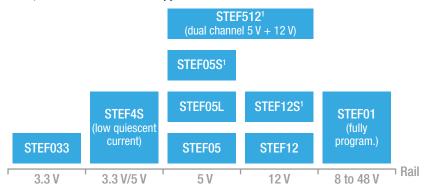
Unlike fuses, they offer complete and flexible management of the fault (overcurrent/overvoltage), without requiring replacement after actuation. They thus help to improve equipment uptime and availability and also reduce maintenance costs and false returns. Compared to traditional protection devices, these new electronic fuses enable versatile and simple programming of protection parameters, such as overcurrent threshold and start-up time.



E-FUSE MAIN FEATURES

- Do not degrade or require replacement after a trip event
- Programmable over-current protection and turn-on time
- Latched or autoretry function
- Overvoltage clamp
- Over-temperature protection
- Integrated power device
- Internal undervoltage lockout

E-fuses, a smart offer for a lots applications



MAIN APPLICATIONS



Home appliances STEF05, STEF01, STEF12, STEF12S¹



HD and SSD STEF033, STEF05, STEF05L, STEF4S, STEF12, STEF05S¹, STEF12S¹, STEF512¹



USB connections STEF05, STEF05L, STEF05S¹



Factory automation STEF01, STEF12, STEF12S¹



Set-top boxes STEF12, STEF12S¹

Power breakers

Connected in series to the power rail, ST's **power breakers** are able to disconnect the electronic circuitry if power consumption exceeds the programmed limit. When this happens, the device automatically opens the integrated power switch, disconnecting the load, and notifies the remote monitoring feature.

STMicroelectronics' STPW programmable electronic power breaker family provides a convenient, integrated solution for quickly and safely disconnecting a faulty load from a 12 V bus.

Inserted between the power rail and the load, the STPW power breakers contain a low-resistance ($50 \text{ m}\Omega$) power switch and precision circuitry for sensing the load power. If the user-programmed limit is exceeded, the switch turns off and a signal on the dedicated monitor/fault pin informs the host system. In normal operation, this output presents an analog voltage proportional to the load power to permit continuous monitoring.

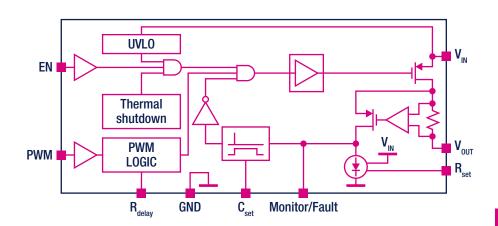
Also featuring built-in auto-restart after a user-adjustable delay, and programmable PWM masking time to prevent protection triggering by inrush current, the STPW family simplifies design for safety and eases certification to standards such as the UL 60730 specifications for abnormal operation. This integrated solution effectively replaces discrete circuitry or a combination of ICs such as a current-sense amplifier or a hot-swap controller plus MOSFET switches, by offering improved accuracy and saving board space and bill of materials for each load protected.

Power breakers

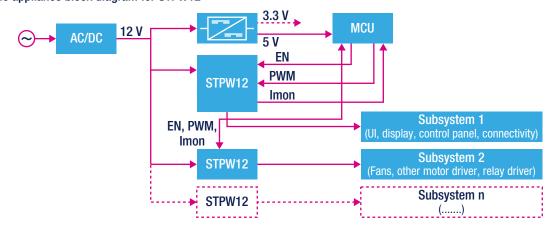
STPW05¹

STPW12

- Auto-retry function with programmable delay
- Adjustable precise power limitation from 11 to 16 W
- 5 V (STPW05) and 12 V (STPW12) rails
- Programmable power limit masking time
- Over-temperature protection
- Integrated N-channel power MOSFET
- Internal undervoltage lockout



Typical home appliance block diagram for STPW12



MAIN APPLICATIONS



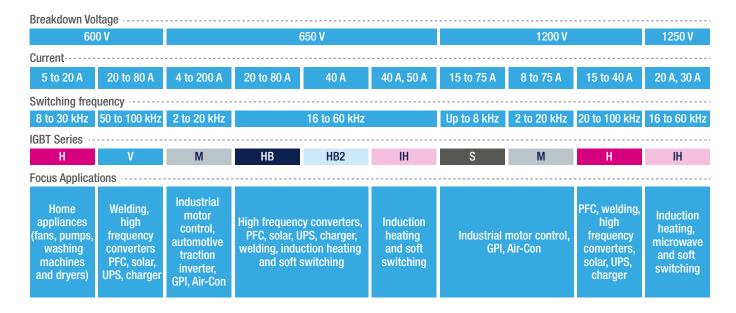




IGBTs

ST offers a comprehensive portfolio of **IGBTs (Insulated Gate Bipolar Transistors)** ranging from 600 to 1250 V in trench-gate field-stop (TFS) technologies.

Featuring an optimal trade-off between switching performance and on-state behavior (variant), ST's IGBTs are suitable for industrial and automotive segments in applications such as general-purpose inverters, motor control, home appliances, HVAC, UPS/SMPS, welding equipment, induction heating, solar inverters, traction inverters, on-board chargers & fast chargers.



H series

STG*H*

600 V family

- 3 µs of short-circuit capability
- Low saturation voltage
- · Minimal collector turn-off
- Series optimized for home appliance applications

1200 V family

- 5 μs of short-circuit capability @ starting $T_{\perp} = 150~^{\circ}C$
- · Low turn-off losses
- Up to 100 kHz as switching frequency

V series

STG*V60*F

- High f_{sw} series
- · Tail less switching off
- Very low turn-off switching losses
- Soft and very fast recovery antiparallel diode
- Up to 100 kHz in hard switching topologies

M series

STG*M* 650 V family

- 6 μs of min short-circuit capability @ starting T₁ = 150 °C
- Wide safe operating area (SOA)
- Very soft and fast recovery antiparallel diode
- Suitable for any inverter system up to 20 kHz
- AEC-Q101 qualified devices

1200 V family

- 10 μ s of min short-circuit capability @ starting $T_{\perp} = 150 \, ^{\circ}\text{C}$
- Freewheeling diode tailored for target application
- · Suitable for any inverter system up to 20 kHz

HB series

STG*H*B

- Low saturation voltage
- · Minimal tail current turn-off
- Different diode option
- Optimum trade-off between conduction and switching losses
- · Low thermal resistance
- 4 leads package available
- Very high robustness in final application
- Automotive eligible

HB2 series

STG*H*FB2

- · Very low saturation voltage
- · Reduced gate charge
- · Different diode option
- · Optimum trade-off between conduction
- · and switching losses
- · Low thermal resistance
- 4 leads package available
- High efficiency in final application
- · Automotive eligible

IH series

STG*IH*

650 V family

- Very low V_{CE(sat)}: 1.5 V @ I_{CN}
- Very low E_{off}
- · Low drop forward voltage diode
- Designed for soft commutation application only

1250 V family

- · Minimized tail current
- Very low drop freewheeling diode
- Tailored for single-switch topology

S series

STG*S120DF3

- 10 μs of short-circuit capablity
 ② starting T₁ = 150 °C
- Wide safe operating area (SOA)
- Soft and fast recovery antiparallel diode
- Low drop series: very low V_{CE(sat)}
- Suitable for very low frequency application, up to 8 kHz

MAIN APPLICATIONS











Home appliances

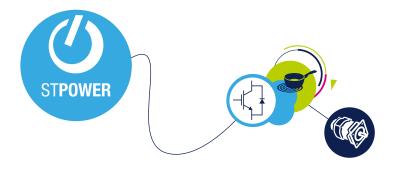


Air conditioning



Motor control





Intelligent power module - SLLIMM™

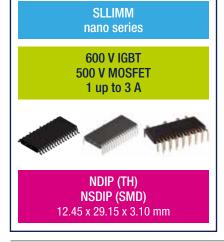
The SLLIMM, small low-loss intelligent molded module, is the ST's family of compact, high efficiency, dualin-line **intelligent power modules (IPM)**, with optional extra features. This family includes different solutions in terms of package(SMD, through hole, full molded and DBC) and silicon technology (IGBT, MOSFET and Super Junction MOSFET). The best compromise between conduction and switching energy with an outstanding robustness and EMI behavior making the new products ideal to enhance the efficiency of compressor, pumps, fans and any motor drives working up to 20 kHz in hard switching circuitries and for an application power range from 10 W to 3 KW.

KEY FEATURES

- 600 V, IGBT based from 3 A to 35 A DC rating at 25 °C
- 600 V, Super Junction MOSFET based from 3 A to 15 A DC rating at 25 °C
- 500 V, MOSFET based, 1 A and 2 A DC rating at 25 °C
- Low V_{CF(sat)}, Low R_{DS(on)}
- · Optimize driver and silicon for low EMI
- Lowest Rth value on the market for the DBC package versions
- Internal bootstrap diode
- Maximum junction temperature: 175 °C for IGBT and 150 °C for SJ-MOSFET
- Separate open emitter outputs
- NTC on board
- Integrated temperature sensor
- Comparator for fault protection
- · Shutdown input/fault output
- Isolation rating of 1500 Vrms/min

KEY BENEFITS

- Easy to drive through microcontroller
- Higher robustness and reliability
- Plug'n Play solution







10 W 100 W 500 W 3000 W Power

MAIN APPLICATIONS









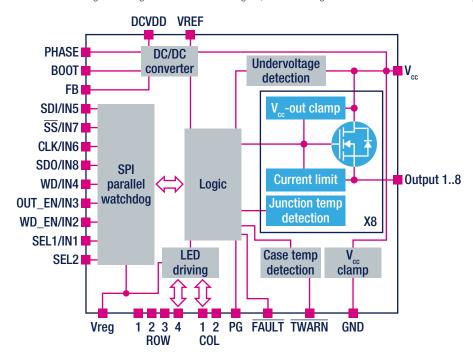


www.st.com/igbt

INTELLIGENT POWER SWITCHES

STMicroelectronics offers **intelligent power switches** (IPS) for low- and high-side configurations. ST's IPS feature a supply voltage range from 6 to 60 V, overload and short-circuit protection, current limitation set for industrial applications, different diagnostic types, high-burst, surge and ESD immunity, very low power dissipation and fast demagnetization of inductive loads.

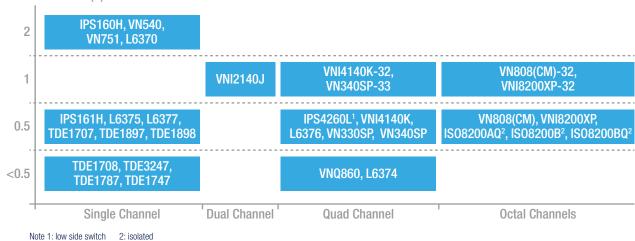
Devices are designed using ST's latest technologies, thus offering state-of-the-art solutions in any application field.



IPS MAIN FEATURES

- Logic
- Driving
- Protections
- Diagnostic
- Power stage
- ...all an a single chip

Output Current/Channel (A)



MAIN APPLICATIONS





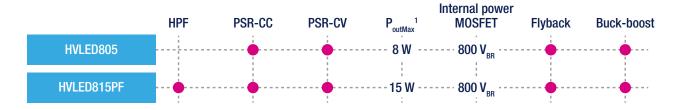


LED DRIVERS

Offline LED drivers

Dedicated **LED drivers** operating from the AC mains ensure highly-accurate LEDs managing to provide a high level of light quality and avoid flickering. By combining a state-of-the-art low-voltage technology for the controller and an extremely robust 800 V technology for the power MOSFET in the same package, HVLED8* converters (i.e controller + MOSFET in the same package) feature an efficient, compact and cost-effective solution to drive LEDs directly from the rectified mains. This family of converters works in constant-current / constant-voltage primary-side regulation (PSR-CC/CV). HVLED001A and HVLED001B controllers are also available for high power needs working in constant-voltage (PSR-CV) primary-side regulation; a dimming function is also available. For both families (HVLED converters and controllers), the primary-side regulation cuts bill-of-material costs, while also simplifying design and reducing the space occupied by LED control circuitry.

Offline LED converters with PSR



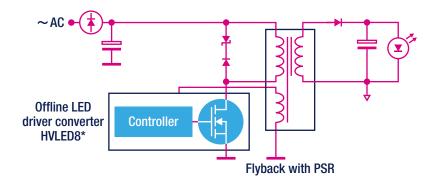
Offline LED controllers with PSR



Offline LED controllers



Topology example



MAIN APPLICATIONS





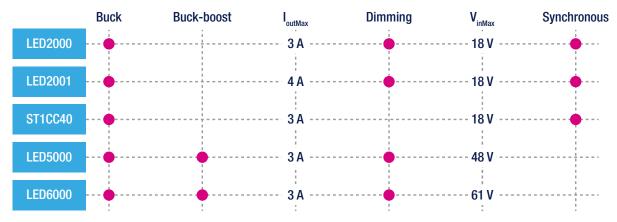


Commercial and street lighting
HVLED001A, HVLED001B, HVLED007

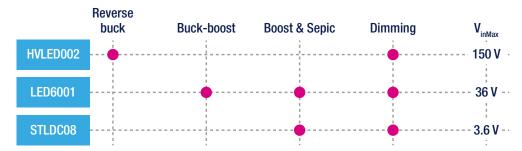
DC-DC LED drivers

ST's monolithic buck switching regulators offer input voltage capability up to 61 V and deliver output currents up to 4 A with high switching frequency. They enable simple, efficient and cost-effective solutions for driving high-brightness LEDs. They also feature dedicated circuitry for dimming. Boost regulators provide the necessary high voltages to drive multiple LEDs in series, guaranteeing accurate LED current matching.

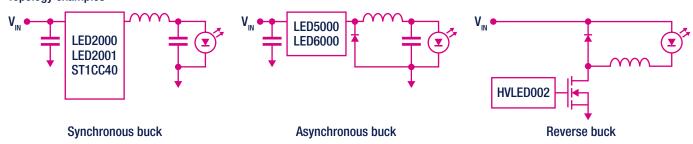
DC-DC LED drivers converters



DC-DC LED drivers controllers



Topology examples







Halogen bulbs replacements and home appliances LED5000, LED6000



Traffic signals LED2000, LED2001, ST1CC40, LED5000, LED6000



Street lighting LED5000, LED6000, HVLED002



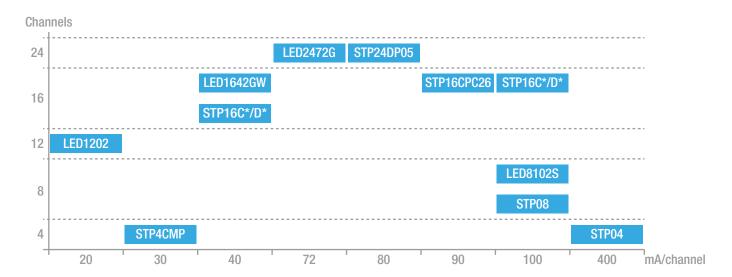
Emergency lighting LED6001, ST1CC40



Commercial and architectural lighting LED5000, LED6000, LED6001, HVLED002

LED array drivers

ST's **LED array drivers** fully integrate all functions required to drive high-brightness LEDs. These devices allow constant-current control in a single-chip solution. The external parts are reduced to only one resistor that sets the preferred maximum current for all outputs. Devices also come with additional features such as high current, high precision, local and global LED brightness adjustment, thermal shutdown, error detection and auto power-saving functionalities.



24 channel RGB (8x3) drivers

- Current gain control (LED2472G), constant current (STP24DP05)
- Error detection
- Autopower saving (LED2472G)

12/16 channel drivers

- Current gain control (LED1642GW), constant current (STP16C*/D*)
- Error detection (STP16C*/D*)
- Dot correction (LED1202)
- · Autopower saving
- Local dimming (LED1642GW, LED1202), global dimming (STP16C*/D*)

4/8 channel drivers

- Constant current
- Direct I/O (LED8102S)
- Error detection (STP08)
- Global dimming

MAIN APPLICATIONS



Traffic signals LED8102S, LED2472G, STP24DP05, STP04



Large panel signs LED1642GW, LED2472G, STP24DP05, STP16, STP08



Home appliances LED8102S, STP16, STP08, LED1642GW, STP4CMP



Special lighting STP04, LED1642GW, LED2472G, LED8102S



wearable/ High End consumer LED1202

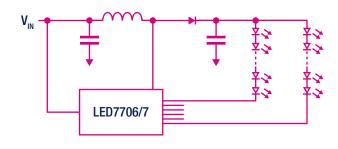
LED row drivers

LED row drivers are essentially boost regulators that provide the necessary high voltages to drive multiple LEDs in series, guaranteeing accurate LED current matching.

ST offers both single- and multi-channel high-efficiency boost LED drivers featuring a wide dimming range, low noise and small footprint. They also embed protection functions such as overvoltage and overcurrent protection, thermal shutdown and LED-array protection.

LED row driver converters



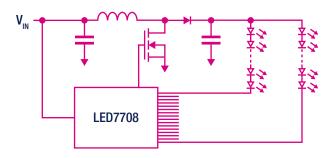


LED row driver controllers

16 rows

LED7708

- 85 mA/row
- Grouped or independent row dimming

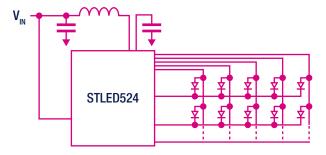


LED matrix driver

5 x 24 matrix

STLED524

- 20 mA/dot
- Adjustable luminance for each LED (dot)







Smartphones STLED25, STLD40D



Keyboard and accessories STLA02*

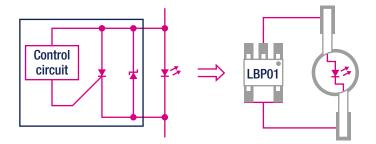


Home appliances and ATMs LED7706, LED7707, LED7708, STCS*



LED bypass protection

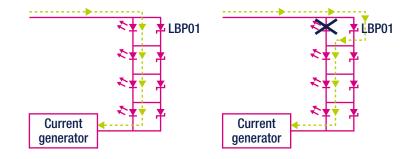
The LBP01 series of LED bypass protection devices are bypass switches that can be connected in parallel with 1 or 2 LEDs. In the event of a LED failure, this device shunts the current through other LEDs. It also provides overvoltage protection against surges as defined in IEC 61000-4-2 and IEC 61000-4-5



LBP01 get reliable your led application

LBP01

- Keep LED strings on in case of LED open mode failure
- Reduced maintenance cost
- Increase lifetime of the lighting system



MAIN APPLICATIONS



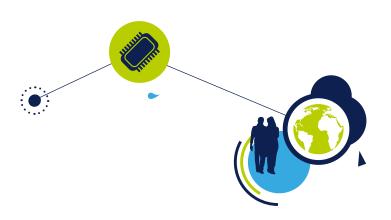






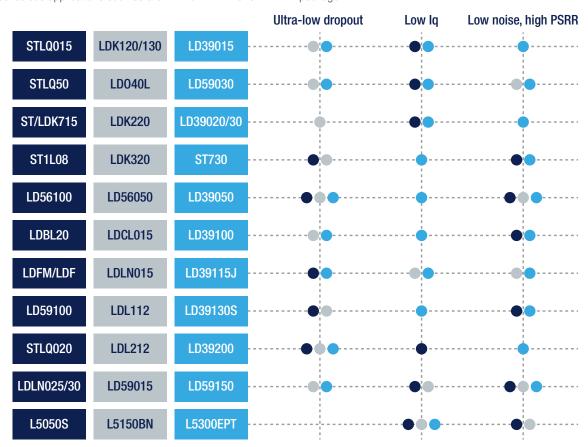
Residential, commercial, architectural and street lighting

Emergency lighting



LINEAR VOLTAGE REGULATORS

ST offers a complete portfolio of industry-standard **high-performance regulators** for both positive and negative outputs. Among our products, you can find the optimal combination of ultra-low dropout voltage (from 50 to 220 mV for 100 mA to 3 A load current) and low quiescent current - for the highest efficiency design – (from 0.3 to 20 μ A for 50 mA to 2 A) or dynamic performance for the best transient response, power supply ripple rejection (up to 92 dB at 1 kHz) and low noise (as low as 6.3 μ Vrms). All this coupled with a choice of the smallest form factor packages for size-conscious applications such as a 0.47 x 0.47 mm STSTAMPTM package.



Ultra-low dropout

- High efficiency in low-/medium-power applications
- · Best cost/performance trade-off
- Large offer for lout capability and packaging

Low quiescent current Iq

- · Extending battery life
- Suitable for space-constrained battery-powered applications

Low noise, high PSRR

- High signal fidelity
- Reduced size of external filter components

MAIN APPLICATIONS







Tablets, smartphones, and wearables LD39115, LD39130, LD39020/30, ST1L08, LDBL20, LD59015, LDLN025/30, STLQ020, LD56030, LD56050, LD56100



Healthcare STLQ015, STLQ020, ST715, LD39130



Home appliances LDK220/320, LDF, LDFM, LDL212



Automotive ADAS, ECU LDK130, LD39100, LD59150, LD040L

LNB SUPPLIES

LNB supplies ICs

ST's **LNB (low-noise block) supply ICs** are intended for analog and digital satellite receivers, satellite TVs, satellite PC cards. These devices are monolithic voltage regulator and interface ICs specifically designed to provide the 13/18 V power supply and the 22 kHz tone signaling to the LNB downconverter in antenna dishes or to the multi-switch box.



Single tuner ICs

LNBH25S LNBH29 LNBH30

Dual-tuner IC

LNBH26S

Main common features

- Complete interface between LNB and I²C bus
- 15 output voltage levels
- Output surge robustness up to 40 V
- P2P compatibility between single- and dual-tuner versions
- Stable with ceramic and electrolytic capacitors
- Built-in high-efficiency 12 V DC-DC converter
- · Selectable output current limit by external resistor
- Compliant with main satellite-receiver output-voltage specifications
- Accurate built-in 22 kHz tone generator suits widely accepted standards
- Internal overload and over-temperature protection

MAIN APPLICATIONS Set-top boxes and PC card satellite receiver



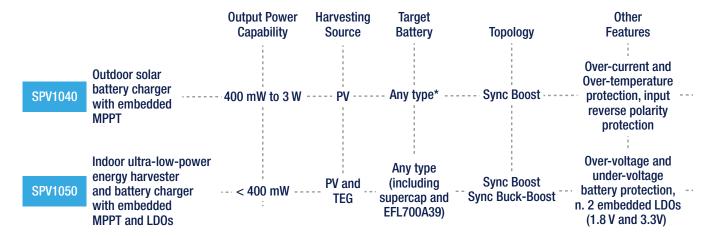
PHOTOVOLTAIC ICs

DC-DC converters with embedded MPPT algorithm

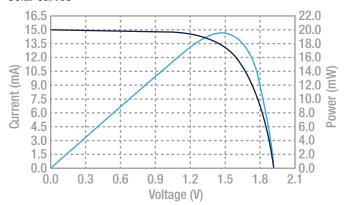
The maximum power point tracking (MPPT) algorithm maximizes the power output by photovoltaic panels according to temperature and solar irradiation conditions.

The SPV1040 is a monolithic DC-DC synchronous boost converter able to harvest the energy generated by even a single solar cell characterized by a very low output voltage. It is especially designed to work in outdoor environments with loads up to about 3 W.

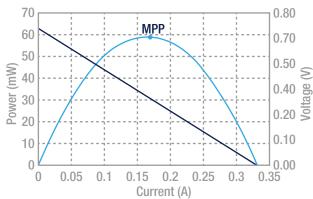
The SPV1050 is an ultra-low-power battery charger and energy harvester (from photovoltaic cells or a thermo-electric generators) that guarantees a very fast charge of supercapacitors and any type of battery including thin-film solid-state batteries. It is specifically designed to work in indoor environments or with very small thermal gradients with loads up to about 350 mW.



Solar curves



Thermo-electric generator (TEG)

















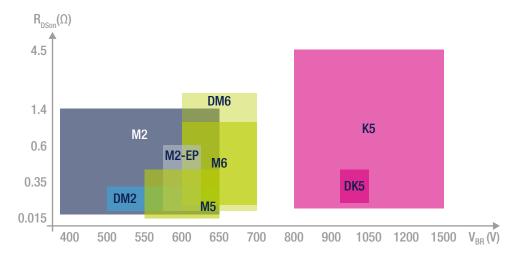


Fitness, climate, home and factory automation monitoring SPV1050

POWER MOSFETS

High-voltage power MOSFETs (silicon)

ST's HV **MOSFET** portfolio offers a broad range of breakdown voltages from 400 to 1500 V, with low gate charge and low on-resistance, combined with state-of-the-art packaging. ST's MDmeshTM high-voltage MOSFETs technology has enhanced power-handling capability, resulting in high-efficiency solutions. Supporting applications for a wide voltage range such as switch mode power supplies, lighting, DC-DC converters, motor control and automotive applications, ST has the right MOSFET for your design.



K5 series

ST*N*K5

- Very low R_{DS(on)}
- · Small Qg and capacitance
- Small packages available
- Suited for hard switching topologies

M5 series

ST*N*M5

- Extremely low R_{DS(on)}
- · High switching speed
- Suited for hard switching topologies

M2/M2-EP series

ST*N*M2

ST*N*M2-EP

- Extremely low Q
- · Optimized for light load conditions
- Tailored for high-frequency applications (M2-EP)
- Suited for hard switching & ZVS/LLC topologies

DM2 & DM6 series

ST*N*DM2

ST*N*DM6

- Improved trr of intrinsic diode
- High dV/dt capability
- Suited for ZVS/LLC topologies

DK5 Series

ST*N*DK5

- Lowest trr @ Very High Voltage BVDSS
- · High dV/dt capability
- Targeting high power 3-phases industrial equipment

M6 series

ST*N*M6

- Lower RDS(on) x area vs previous generation
- Extremely low gate charge (Qg)
- Optimized capacitances profile for better efficiency @ light load
- Optimized threshold voltage (VTH) and gate resistance (RG) values for soft switching

MAIN APPLICATIONS



Adapters K5, M5, M2, M2-EP, M6







Solar inverters, welding, HEVs, and UPS K5, M5, DM2, DM6, DK5





Residential, commercial, architectural and street lighting K5, DK5



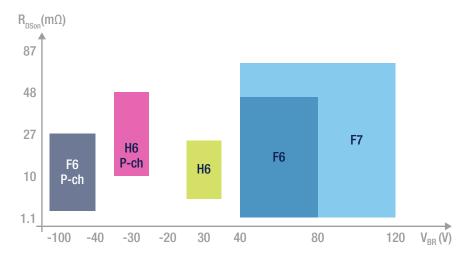
Server/Telecoms M5, M2, M2-EP, DM2

www.st.com/mosfet

Low-voltage power MOSFETs (silicon)

ST's LV **MOSFET** portfolio offers a broad range of breakdown voltages from -100 V to 120 V, with low gate charge and low on-resistance, combined with state-of-the art packaging.

ST's STripFET MOSFETs support a wide voltage range for synchronous rectification, UPS, motor control, SMPS, power-over-Ethernet (PoE), inverter, automotive and other applications in a wide range of miniature and high-power packages: DPAK, D2PAK, SOT-223, TO-220, TO-220FP, TO-247, PowerFLAT (5×6)/(3.3×3.3)/(2×2), SO-8 and SOT23-6L.



H6 series

ST*N*H6

- Very good R_{DS(on)}
- Soft diode recovery
- Suited for OR-ing, square-wave HB, battery mgmt topologies

F6 series

ST*N*F6

- · Wide voltage range
- Soft diode recovery
- Very good R_{DS(on)}
- Suited for load-safety switch, buck and sync rectification

F7 series

ST*N*F7

- Extremely low R_{DS(on)}
- Optimized body diode (low Q_{rr}) and intrinsic capacitance
- Proper Crss/Ciss ratio
- Suited for flyback and sync rectification

MAIN APPLICATIONS



Small motor control and USB battery chargers F6





HDD, power tools, STB, and game consoles
H6

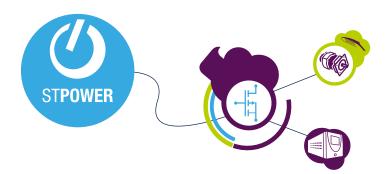


Server/Telecoms and SMPS F7



UPS, e-bikes, and fans F6, F7





www.st.com/mosfet

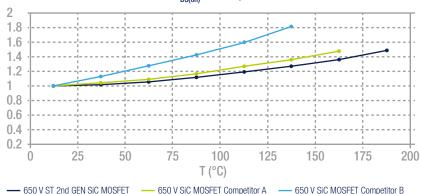
SiC MOSFETs

Based on the advanced and innovative properties of wide bandgap materials, ST's silicon carbide (SiC) MOSFETs feature very low R_{DS(no)} per area for the new 650 V/1200 V G2 product families, combined with excellent switching performance, translating into more efficient and compact designs.

ST is among the first companies to produce high-voltage SiC MOSFETs. These new families feature the industry's highest temperature rating of 200 °C for improved thermal design of power electronics systems.

Compared to silicon MOSFETs, SiC MOSFETs also feature significantly reduced switching losses with minimal variation versus the temperature. These features render the device perfectly suitable for high-efficiency and high power density applications.

ST's SiC Mosfet 650 V - Normalized $R_{\mbox{\tiny DS(on)}}$ vs Temperature



SiC MOSFETs **MAIN BENEFITS**

- Smaller form factor and higher power density
- Reduced size/cost of passive components
- Higher system efficiency
- · Reduced cooling requirements and heatsink size

SiC MOSFETs, the real breakthrough in high voltage switching

SCT*N120G21

SCT*N65G2

- $V_{PR} = 1200 \text{ V (SCT*N120G2)},$ 650 V (SCT*N65G2)
- Low power losses at high temperature
- High operating temperature capability (200 °C)
- Body diode with no recovery losses
- Low power losses at high temperatures
- Easy to drive
- Low gate charge (SCT*N65G2)



INNOVATIVE PACKAGES



STPAKTM Multi Sintering Package: Ready for the Next Generation **EV Traction Inverters**



HU3PAKTM Top Side Cooling Package: Ready for Industrial & Automotive High Performance Application



Motor drive & factory automation



(Traction Inverter, OBC, DC/DC)



Charging station

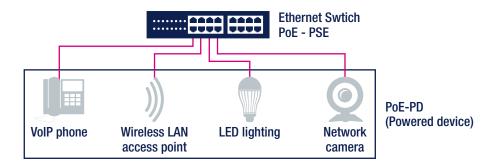


UPS & Data center Power supply



POWER OVER ETHERNET ICS

Power over Ethernet (PoE) is a widely adopted technology used to transfer both data and electrical power over an RJ-45 cable. ST offers solutions for PoE applications on the powered devices (PD) side that integrate a standard power over Ethernet (PoE) interface and a current mode PWM controller to simplify the design of the power supply sections of all powered devices. ST's **PoE-PD ICs** are compliant with both the more recent IEEE 802.3bt specification.



PoE-PD devices

PM8803

- IEEE 802.3at PD interface
- PWM current mode controller with double gate driver
- Integrated 100 V, 0.45 W, 1 A hot-swap MOSFET
- Supports flyback, forward active clamp, and flyback with synchronous rectification topologies

PM8801

- Sleep mode with LED indicator and Maintain Power Signature
- IEEE 802.3at PD interface + PWM current mode ctrl with double gate driver
- Integrated 100 V, 0.45 W, 640 mA hot-swap MOSFET
- Supports flyback, forward active clamp, and flyback with synchronous rectification topologies

PM8800A

- IEEE 802.3af PD interface
- PWM current mode controller
- Integrated 100 V, 0.5 W, 800 mA hot-swap MOSFET
- Supports both isolated and non-isolated topologies

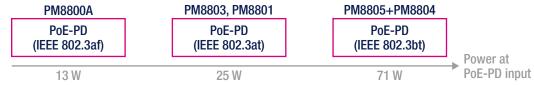
PM8804

- PWM current mode controller
- Double Gate Driver
- Support Isolated Active Forward Converter
- Input voltage up to 75 VDC
- Embedded start-up (20 mA)
- Slope compensation
- Programmable fixed frequency (up to 1 MHz)

PM8805

- IEEE 802.3bt PoE-PD interface
- System in Package
- Dual Active bridges
- HotSwap MOSFET
- Compact package (10 times smaller than discrete BOM) with high thermal performances
- 100 W capability

Main standards



Power over Ethernet power supply protection

PEP01-5841

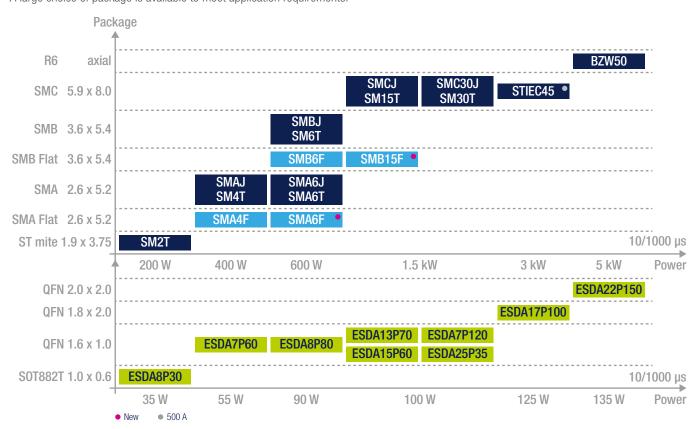
- Power supply protection compliant with IEC61000-4-5 Level 2:1 kV
- Allow to use 100 V power MOSFET
- Stand off voltage: 58 V
- Surface mount SO-8 package

www.st.com/PoE

PROTECTION DEVICES

Transil

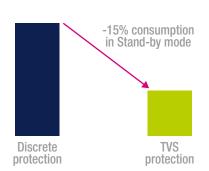
The **Transil** is an avalanche diode specially designed to clamp over voltages and dissipate high transient energy. Transil are power devices to protect applications against Electrical Over-Stress (EOS) and specifically against surge events as defined by IEC 61000-4-5. A large choice of package is available to meet application requirements.

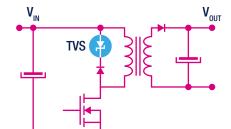


TVS Transil series against repetitive overvoltage in high temperature conditions

TVS

- Clamping voltage characteristics defined at 25 °C, 85 °C and 125 °C
- Stand-off voltage range: from 85 V to 188 V
- Low leakage current: 0.2 μA at 25 °C
- Maximum operating junction temperatures:
 - SMB and SMC: 150 °C
 - D0-15 and D0-201: 175°C





MOSFET Protection with TVS

MAIN APPLICATIONS









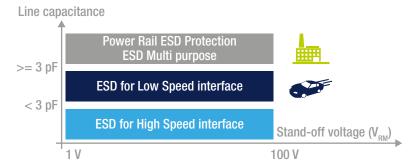


Residential, commercial, architectural and street lighting

ESD protection

Driven by market needs, ST's **ESD protection** devices are available as single line devices for flexibility and multi-line arrays for integration in compact application. All this devices are rated according to IEC 61000-4-2 and specific requirements, such as low capacitance, bandwith for high speed lines.

A large choice of package is available to meet application requirements.



Power delivery Protections

Ultimate TVS protection for USB fast-charging ports

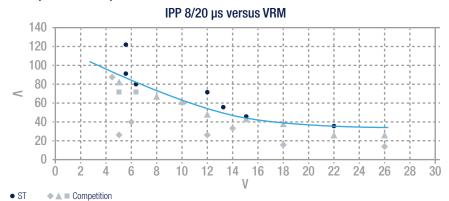
ESDAxxP

Strong and thin protection, the ESDAxxP-1U1M series helps to stop damages due to the surge events

KEY FEATURES & BENEFITS

- Complete voltage range 5 V, 9 V, 12 V, 15 V and 20 V.
- A unique small and thin package for all the voltages (1.0 mm x 1.6 mm x 0.55 mm) minimizing the PCB area consumption.
- Highest housed 8/20µs IPP in the market, from 35 A to 120 A.

Peak pulse current performances



	Protection	
Stand-off voltage (V _{RM})	High surge current compact protection (V _{BUS})	Single and multi lines protection for MCUs Communication Channel (CC) and Side Band Use (SBU)
20 V	ESDA25P35-1U1M ESDA24P140-1U1M	ESDL20-1BF4 ESDA25W
15 V	ESDA17P100-1U2M ESDA15P50-1U1M	ESDA17P20-1U1M
9 V	ESDA13P70-1U1M	ESDL121-1BU2
5 V	ESDA7P120-1U1M	ESDZV053-1BU2 ESD051-1F4

MAIN APPLICATIONS





Tablets, smartphones, and digital cameras





Healthcare



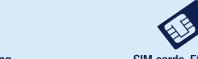
I/O microcontrollers and signal conditioning



Factory automation Human machine interfarce (HMI)



Smart metering

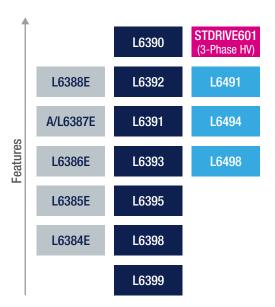


SIM cards, Ethernet, and HDMI/DVI ports

STDRIVE MOSFET AND IGBT GATE DRIVERS

ST's **power MOSFET and IGBT gate drivers** include integrated high-voltage half-bridge, single and multiple low-voltage gate drivers. Robustness and reliability, system integration and flexibility: that's ST's gate driver offer you. In particular the STDRIVE families L639*, L649* and STGAP series offer smart functionalities to protect and simplify application implementation and usage.





TD350

TD352

TD351

PM8851

PM8841

PM8834

STGAP1AS
STGAP2S
STGAP2D

600 V gate drivers

Half bridge

- 4 A source/sink driver high current capability (L6491)
- Integrated bootstrap diode
- Adjustable deadtime (L6494L)
- Comparator, op amp integrated, smart SD, interlocking and program. DT (L6390)
- Extended temperature range (A version)

3-Phase

- Best In Class for propagation delay 85 ns
- 200 mA/350 mA sink / source driver current capability
- Integrated bootstrap diode

Low side gate drivers

- 2 level turn-off (TD35*)
- Miller clamp (TD35*)
- Pulse transf / opto input (TD35*)
- Dual independent low side driver (PM8834)
- 4 A source/sink driver high current capability (PM8834)

Galvanically-isolated single and dual gate driver

- Up 4 kV isolation
- High voltage rail up to 1.7 kV
- Up to 5 A source/sink driver current capability
- 2 Level turn-off (STGAP1AS)
- Miller clamp, negative gate supply
- Optimized for SiC MOSFET driving

MAIN APPLICATIONS

automation appliances





Home



Motor

control



Lighting





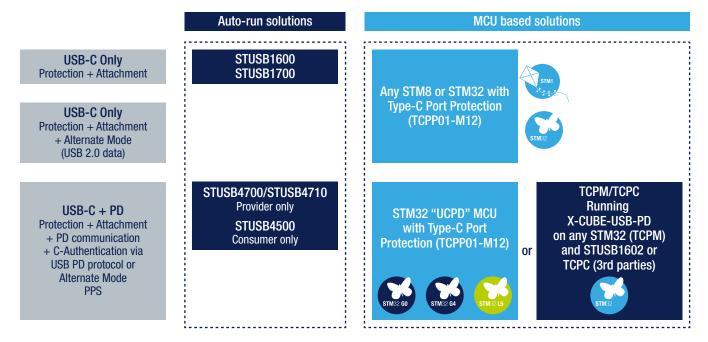
Solar inverters

HEV / EV

www.st.com/stdrive

USB TYPE-C™ AND POWER DELIVERY CONTROLLERS

With an extensive technology and IPs portfolio, ST provide a range of **USB-IF certified solutions for USB type-C and Power Delivery** to support implementations in a variety of sink, source and dual role devices. From USB-Type-C interfaces and PD Controllers to Authentication, ST complements the portfolio with Power Management ICs, full range of **protection** for data and power lines protection. ST's solutions cover from **Type-C port interface ICs** to **USB PD controllers**, and offer, a wide flexibility with hard wired and MCU to fit different use cases and every power ratings.



Auto-run solutions

STUSB Family cover all the applications with optimized partitioning from USB Type-CTM Interface for 15 W device to Power delivery PHY and BMC Driver ICs companion chip of STM32 based solution to standalone Full Hardware USB PD Controller optimized for AC adapters up to 100 W.

MCU based solutions

When only USB-C connector management (reversibility, attachment and role management) is required, any STM8 or STM32 can be used to handle this function (see AN 5225).

A companion Type-C Port Protection device **TCPP01-M12** is proposed for advanced protection of the USB-C connector lines such as CC and Vbus lines.

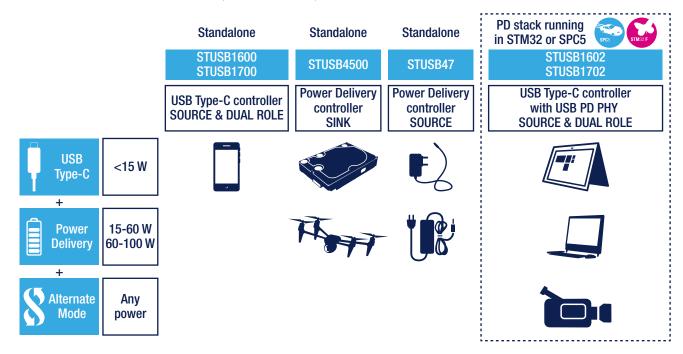
When USB PD protocol is required, two MCU based solutions are possible.

- 1. Using our newest STM32 USB PD3.0 controllers (STM32G0/G4/L5) with built-in "UCPD" interface. Note: UCPD stands for USB-Type-C and Power Delivery interface
- 2. Using a **TCPM / TCPC** topology with our X-CUBE-USB-PD middleware stack running on any STM32 as Type-C Port Manager(TCPM) and interfacing with a Type-C Port Controller (STUSB1602 or TCPC from 3rd parties)



STUSB family of standalone (auto-run) USB-C and Power Delivery controllers

STUSB family is manufactured using ST's 20 V process technology, the certified STUSB Family controller IC integrates short-circuit, overvoltage, over-current protection to eliminate the need for external circuitry. Additionally, it offers plug power support (VCONN) with up to 600 mA programmable current capability and, per the USB Power Delivery specification, it integrates Bi-Phase Mark Coded (BMC) Physical Layer (PHY) coding and decoding logic. Integration of such features in a single-chip Type-CTM controller enables fast migration to USB Type-CTM, while minimizing MCU-resource requirements compared to alternate solutions. STUSB Family cover all the applications with optimized partitioning from USB Type-CTM Interface for 15 W device to Power delivery PHY and BMC Driver ICs companion chip of STM32 based solution to standalone Full Hardware USB PD Controller optimized for AC adapters.



STUSB Family: main common functions

- Type-CTM attach and cable orientation detection
- · VBUS switch gate driver
- · VBUS voltage monitoring

STUSB1600

- · Roles: Source/Sink/Dual Role Power
- OVP, OCP, UVP, short protection
- Integrated VBUS discharge
- Direct interface to MCU through I²C + IRQ
- Accessory & dead battery support

STUSB1700

- Role: Source
- GPIO-controlled current profile (Power sharing, Thermal protection)
- VBUS powered (no LDO needed)
- VDD = (4.1 V 22 V)
- 28 V short to VBUS protection
- Certification test ID: #1100100

- Short-to-VBUS protection on CC pins (22 V) and VBUS pins (28 V)
- Report (optional) of majors events to the Head Unit / MCU (connection, disconnection, power budgets, errors etc...)
- Configurable start-up profiles (embedded FTP memory)

STUSB1602

STUSB1702

- Role (1602): Source/Sink/Dual Role Power
- Role (1702): Source Auto Grade
- Integrated Type-C PHY + BMC coding
- Perfect companion chip to EC to manage USB Type-C port
- Integrated VCONN switch
- Adjustable current limit (600 mA max)
- OVP, OCP, UVP, short protection
- Integrated VBUS and VCONN discharge nath
- I²C, SPI + IRQ MCU interface Dual I²C address support
- Accessory & dead battery support

STUSB47

- Role: Source
- Offers up to 5 programmable PDOs
- Full hardware solution no software
- Internal and/or external VBUS discharge path
- · Very low power consumption
- I²C interface (optional connection to MCU)

STUSB45

- · Role: Sink
- Standalone PD controller with Dead Battery support
- VBUS powered (zero power on Vbat)
- VDD = (4.1 V 22 V)
- 28 V short to VBUS protection
- Optional I²C interface for dynamic power management

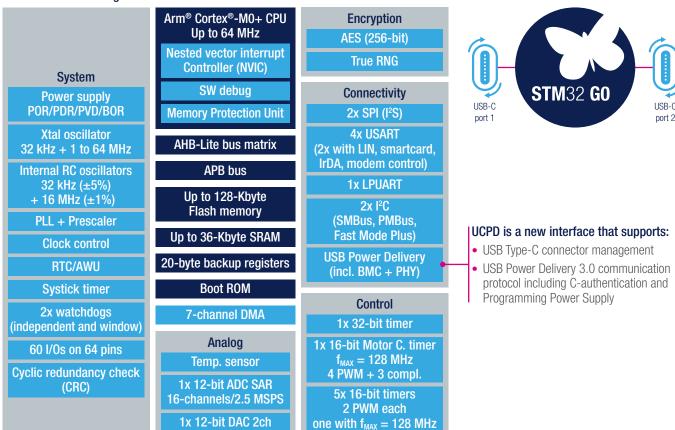
STM32 USB PD3.0 controllers

Introduced in December 2017, **STM32G0** is the world's 1st standard USB PD 3.0 microcontroller with a UCPD interface (UCPD stands for USB-Type-C and Power Delivery).

This new IP, available in **STM32G0/G4/L5** series, allows to develop USB-C sink, source and dual role devices in a wide range of embedded applications.

UCPD enabled STM32G0/G4/L5 provides a high flexibility to migrate embedded applications to USB-C and Power Delivery technology while managing other application environment thanks to the versatile feature set and peripherals available in a traditional MCU. UCPD is certified PD3.0 and support all new features such as C-Authentication and Programming Power Supply (PPS).

STM32G081 block diagram



STM32G0 USB-C Ecosystem: for short time-to-market

Our STM32G071B-DISCO kit allows to discover and display USB-C power and feature capabilities of any USB-C complaint host. Associated with our professional-grade STM32CubeMonitor-UCPD software GUI, the kit acts as a USB PD analyzer and allows customer to debug, configure and inject in one click USB PD3.0 packets while monitoring Vbus voltage and Ibus current between two USB-C devices. Our well-known STM32 configurator STM32CubeMx supports easy setting of UCPD.

2x Low-power timers

An evaluation board STM32G081B-eval is proposed with two USB-C ports offering 45 W of power with different profiles.

2x comparators



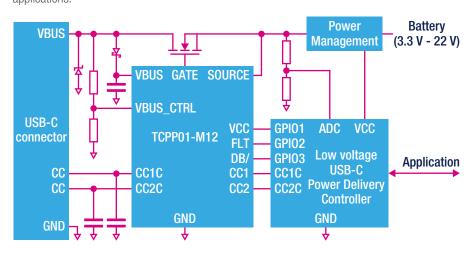




Type-C Port Protection

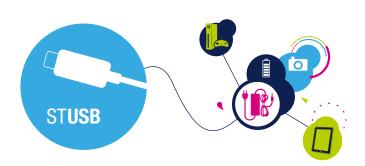
TCPP01-M12

The **TCPP01-M12** (type-C port protection) is a single chip solution for USB type-C port protection that facilitates the migration from USB legacy connectors type-A or type-B to USB type-C connectors. The TCPP01-M12 features 22 V tolerant ESD protection as per IEC61000-4-2 Level 4 on USB type-C connector communication channel (CC) and V_{BUS} lines. To allow fast certification for USB power delivery, the TCPP01-M12 provides overvoltage protection on CC1 and CC2 pins when these pins are subjected to short circuit with the V_{BUS} pin that may happen when removing the USB type-C cable from its receptacle. For sink applications, TCPP01-M12 triggers an externally programmable N-MOSFET overvoltage protection on V_{BUS} pin when a defective power source applies a voltage higher than selected OVP threshold. Also, the TCPP01-M12 integrates a "dead battery" management logic that is compliant with the USB power delivery specification. The V_{BUS} N-MOSFET load driver can also be used in source applications.



KEY FEATURES

- ESD protection for CC1, CC2 and VBUS
- Compliant with IEC 61000-4-2 Level 4 (± 8 kV contact discharge, ±15 kV air discharge)
- Over Voltage Protection on CC lines against short-to-VBUS overvoltage
- Externally programmable Over Voltage Protection on VBUS line
- Integrated VBUS gate driver for external N-MOSFET
- Over Temperature Protection
- Integrated "Dead Battery" management
- Open-drain fault reporting
- Operating junction temperature from -40 °C to 85 °C
- ECOPACK®2 compliant





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